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Solution-processed OLEDs for printing displays

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Low-cost and large-scale fabrication technologies are highly desirable for fabricating organic light-emitting diodes (OLEDs) for applications in full-color displays and solid-state lighting. Particularly, printed OLEDs have attracted extensive attention and have great application potential in the fields of commerce, medicine, education and so on. Compared with the vacuum evaporation technique, the printing method has a high material utilization rate and does not need harsh preparation conditions. This review will introduce the development background and advantages of solution-processed OLEDs for printing displays, summarize research progress of light-emitting materials and basic theories of solution-processed OLEDs, and expound on the characteristics of the printing preparation process and the related challenges. Finally, a brief perspective on the future development trend and infinite potential of printed OLEDs will be presented for the commercialization of printing displays.

1. Introduction

Organic light-emitting diodes (OLEDs) are considered to be the development direction of displays in the future due to their advantages of low power consumption, self-illumination, high flexibility, rich color and fast response.^{1,2} Therefore, OLEDs

have been rapidly developed and applied to the fields of displays and lighting, such as in-vehicle displays, flat panel displays, TV screens and so on. In particular, in the aspect of screen displays, compared with liquid crystal displays (LCDs), OLED pixels cannot produce light and do not consume electric energy after being turned off, resulting in them displaying true black and saving energy.^{3–6}

OLEDs have enabled the industrialization of some products, so the development and research of OLEDs are of great significance in the fields of commerce, medicine, lighting and displays. However, due to the high price and low yield, OLEDs are mainly widely used in small-size displays, while LCDs still dominate in large-size displays.^{3,7,8} At present, large-size OLEDs are mainly realized by printing methods. Although the utilization rate of printed OLED materials (more than 90%) is

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higher than that of evaporated OLEDs (less than 20%), they do not require complex preparation conditions for the vacuum evaporation technique, which results in significant cost savings. But, unlike solid evaporated OLED materials, printed OLED materials are usually liquid and the properties of most organic materials are usually not very stable. Therefore, the materials available for fabricating printed OLEDs are not enough for their mass production, which has become a major factor restricting their mass production. In addition, for large-scale production the processing time also needs to be controlled as much as possible, which results in higher requirements for printing equipment and drying equipment. In general, there are many difficulties to overcome in developing OLED materials that can meet both mass production and performance requirements.

Printed OLED technology refers to the technology of transferring each layer of organic materials to a substrate to prepare devices through a solution treatment process. The core of the printed OLED technology is to realize the construction of an

optimized carrier transmission structure through a solution treatment process, including process-matched material formulations, preparation of high-quality functional films, and effective integration of light-emitting units and thin-film transistor (TFT) control units. The basic feature of a printed OLED display is that the light-emitting layer can be prepared by a printing process (mainly inkjet printing), and the other organic functional upper and lower layers can also be prepared by printing processes such as inkjet printing, screen printing, spin-coating, spraying, scraping, embossing, *etc.* or by the evaporation process. Among them, inkjet printing directly prints red, green and blue organic light-emitting materials on a substrate with a nozzle, and has a high utilization rate of materials. Therefore, the research on printed OLEDs is the key development direction of OLED display technology.

In 1990, Burroughes *et al.* discovered that spin-coated polymer PPV (poly(*p*-phenylene vinylene)) could produce luminescence.⁹ In 1998, Hebner *et al.* prepared a color OLED display screen by inkjet printing and a spin coating process for the first time.¹⁰ In 2013, South China University of Technology prepared a full-printed color OLED display. BOE successively developed OLED display screens with high definitions of 4 K and 8 K in 2018 and 2020. Although large-scale and high-resolution printed OLEDs have been preliminarily realized, there are still some problems with these technologies, resulting in their inability to produce large-scale OLEDs: (1) industrialized ink-jet printing equipment is not perfect; (2) the “coffee cup” phenomenon easily occurs when printing OLED films; (3) the pixel structure should be further studied to continuously improve the resolution of the OLED display; and (4) the number of structural layers of printed OLED devices is always limited, which cannot help achieve the arbitrariness of vapor deposition devices. Although the technology of printed OLEDs is not yet mature, it has developed very rapidly. BOE, LG and Samsung



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device integration of metal and semiconductor nanostructures and thin films for a range of device applications including light-emitting diodes and solar cells.

have all launched research on printed OLED technology. It is clear that printing technology has great potential in the field of displays.

Herein, we focus on printed OLEDs. First, we introduce electrodes, injection layers, transport layers and light-emitting layers in detail from the perspective of materials. Next, we introduce the development, progress and difficulties of solution-processed OLEDs from the perspective of stacking, inversion and other common structures. Then, we introduce various possible preparation methods and carry out some comparative studies in terms of film-forming characteristics and device performance, and explain the advantages, disadvantages and development trends of printed OLEDs. Finally, we provide a full discussion and outlook on the future development of printed OLEDs.

2. Solution-processable materials

2.1 Electrodes

The conductivity of electrodes has a great influence on the performance of OLEDs. An excellent transparent electrode should have the following characteristics: (1) good stability, (2) low square resistance, (3) high work function, (4) small roughness, (5) excellent wetting performance and good diffusion of solution on the electrode surface, (6) high transmittance, and (7) low cost. For flexible transparent electrodes, it is also required to have excellent mechanical properties, including a small minimum bending radius and a small change in square resistance caused by periodic bending or stretching. The common conductive electrodes are metal electrodes (such as metal nanowires/metal mesh/ultra-thin metals), carbon nanomaterials (graphene/carbon nanotubes), conductive macromolecules and combination electrodes.

2.1.1 Metal electrodes (metal nanowires/metal mesh/ultra-thin metals). Metals have excellent electrical conductivity and extremely low resistivity. The resistivities of silver, copper, gold, and aluminum are 2 orders of magnitude lower than that of commercial ITO,¹¹ and these metals have good ductility and flexibility. The metal film of the bulk is opaque to light. In order to make the metal electrode transparent, there are two strategies: one is to prepare some “holes” in the metal film, so that light can “penetrate” through, which corresponds to the metal nanowires and metal mesh electrodes and another is to serially reduce the thickness of the metal to a few tens of nanometers, and light can pass through. Typically, the thickness is about 10 nm or less,¹² with the best optoelectronic properties, corresponding to ultrathin metal electrodes.

Metal nanowires have been widely studied because of their excellent photoelectric properties, good flexibility, solution processing, low cost and mass preparation.¹³ The most common one is silver nanowires, followed by copper nanowires and gold nanowires.^{14–17} Due to the characteristics of the crisscross and up-and-down stacking of nanowires, metal nanowire-based conductive films suffer from a significant problem of roughness, which is detrimental to the application of devices such as

OLEDs.¹³ The methods such as embedding nanowires into polymers and compounding other transparent electrodes can be used to solve the problem of roughness.^{18,19} In addition, metal nanowires face instability problems, especially silver and copper nanowires. They are easily eroded by water, oxygen and sulfur in the air environment, and the rate of degradation will be accelerated under light, high temperature and current conditions. Addressing the instability of metal nanowires is an important part in its commercialization process.

Metal mesh refers to a network of metal wires arranged periodically and closely connected with each other.²⁰ It is superior to metal nanowires in two aspects: first, there is no contact resistance and second, the aspect ratio of metal wires is usually controllable and designable. Metal grids can be prepared in various shapes, such as square, triangle, honeycomb, crack, nanogroove network, *etc.* The preparation methods are also diversified, such as lithography, laser sintering, nanoimprinting, electrospinning, template modulation, self-assembly, printing, *etc.*^{21–26} Like metal nanowires, metal grids have the problem of roughness. The method of embedding a grid structure into a polymer substrate or compounding other electrodes is also suitable for metal grids.²⁷ The work function of a metal mesh is determined from the prepared metal, but it needs to be compromised with the other properties of the metal. Gold has a high work function, but it is expensive. The work function of copper is medium, but its stability is poor. Silver is the more common metal, which has high electrical conductivity, but its work function is too low. In addition, there is a common problem in metal grids: discontinuous conductive films and metal wires visible to the naked eye. This will affect the application of metal mesh in high-resolution displays.

An ultra-thin metal electrode refers to the conductive metal with a thickness of several nanometers or tens of nanometers and certain light transmittance. Different from metal nanowires and metal grids, ultra-thin metals are continuous and flat conductive films. According to the types of matching materials, ultra-thin metals can be divided into dielectric/metal/dielectric (DMD) composite multilayer structure films and transparent conducting oxide (TCO)/metal/transparent conducting oxide (TCO/m/TCO) laminated transparent conducting films. The interface properties and thickness of metal layer have a great influence on the photoelectric properties of ultra-thin metals. This involves an important issue. The ultra-thin metal forms a rough three-dimensional island structure during the film-forming process, so as to stimulate plasma resonance, limit conductivity and increase light loss.²⁸ The required critical film-forming thickness increases, even greater than the penetration thickness of the metal, so that light cannot pass through the ultra-thin metal. The idea to solve this problem is to add seed layers such as metals, metal oxides, organic small molecules and composite layers to increase the nucleation density or dope the metal film to inhibit the Volmer Weber three-dimensional growth mode of silver.^{28–32} In 2015, Lee *et al.* reported a method using polyethyleneimine (PEI) as a seed layer, which can greatly reduce the critical film thickness of silver and make the film more continuous, matching

PEDOT:PSS as an anti-reflection layer finally obtained a square resistance of a transparent electrode of $<10 \Omega \square^{-1}$ and a transmittance of more than 95%.³³ Ultra-thin metals also have the advantage of a tunable work function. By changing the matching upper layer material, it can be used as both an anode with a high work function and a cathode with a low work function. However, ultra-thin metals also have stability problems, with poor film adhesion and easy peeling, resulting in complete device failure.

2.1.2 Carbon nanomaterials (graphene/carbon nanotubes).

Carbon nanomaterials can meet the application needs of current flexible electronic devices because of their high electronic transmission rate, light transmittance and good mechanical flexibility. In addition, carbon nanomaterials have the unique advantages of wide sources and flexible and diverse preparation methods, which can reduce materials and production costs, so they are more practical. At present, carbon nanomaterials include graphene and carbon nanotubes. Compared with other transparent electrodes, transparent conductive films based on carbon nanomaterials do not have obvious advantages in light transmission and conductivity, but their outstanding chemical stability, good substrate adhesion, and excellent mechanical flexibility, and the advantages of large-scale preparation and suitability for continuous film preparation, make them still occupy an important position in the research field of new transparent conductive films, especially flexible transparent conductive films.

Graphene is a two-dimensional single-layer film composed of carbon atoms. It is a fundamental component of graphite materials (such as fullerene, carbon nanotubes and graphite). The graphene film electrode has high transmittance (up to 97.7% for single-layer graphene films), low theoretical square resistance, low roughness, good stability, and good flexibility.^{34,35} It has the potential to replace the traditional ITO electrode. It is worth mentioning that the perfect graphene does not penetrate any gas molecules, which means that theoretically water and oxygen cannot penetrate organic optoelectronic devices through the electrodes, resulting in device performance degradation.³⁶ Due to this advantage, graphene can also be used as the encapsulation material of OLEDs.³⁷ According to the preparation method, graphene can be classified into chemical vapor deposition (CVD) graphene, epitaxially grown graphene, mechanically exfoliated graphene, liquid phase exfoliated graphene, and self-assembled graphene.³⁸ Among them, CVD graphene is most suitable for transparent electrodes due to its excellent properties and large-scale preparation potential. The graphene thin film electrode also faces some challenges in practical applications. Firstly, graphene has poor wettability. It is difficult for water-soluble reagents to form a uniform film on their surface. Secondly, the work function of graphene is low, usually between 4.4 eV and 4.6 eV. However, these problems can be effectively solved by surface and interface engineering because graphene can be easily modified.^{39–42} Thirdly, graphene is a thin film with atomic thickness, so it is difficult to control in practical applications. Finally, the current production cost of the CVD graphene film is still relatively high,

which hinders the practical applications of graphene. However, due to the abundant carbon reserves of the graphene raw material in nature and the continuous development of new technologies, such as low-temperature growth technology and roll-to-roll technology, the production cost of the CVD graphene film is expected to be greatly reduced in the future.

Carbon nanotubes can be regarded as a tubular one-dimensional material made of graphene, and its discovery dates back to 1993.⁴³ At present, the macropreparation of carbon nanotube raw materials is mainly performed using a CVD method, which can be manufactured at low cost under low temperature and atmospheric pressure, with an annual production capacity of thousands of tons. The carbon nanotube electrodes are prepared by various conventional solution methods. From the perspective of the electrode, carbon nanotubes can be equivalent to a combination of nanowires and graphene. It inherits the advantages of both. (1) It can be prepared by the solution method, which can reduce the cost; (2) good stability; (3) good mechanical strength and flexibility. However, at the same time, it also inherits the shortcomings of both: (1) carbon nanotubes face the same shortcomings as graphene: the need to dope for improving the carrier concentration or exploring ways to improve mobility to achieve desired conductivity; (2) like nanowires, there are problems of roughness and contact resistance. In particular, the latter greatly reduces the photoelectric performance of the carbon nanotube electrode. A single carbon nanotube can reach a conductivity of $2 \times 10^5 \text{ s cm}^{-1}$ and a mobility of $1 \times 10^5 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, but the randomly distributed undoped carbon nanotube films only obtain a conductivity of $\sim 6600 \text{ s cm}^{-1}$ and a mobility of the order of $1\text{--}10 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$.^{44,45} In a word, carbon nanotubes are more mature than other nanoelectrode materials, but their core photoelectric properties are still poor, and the quality factor of the prepared electrode is not high enough, which needs further research studies.⁴⁶

2.1.3 Conductive macromolecules. At present, the conductivity of some conductive organic polymers may be larger than that of some inorganic semiconductors, showing great utility, among which PEDOT:PSS is representative. It has excellent solution processability and excellent film-forming ability, which can smooth the substrate and reduce the roughness. It has a work function between 4.9 eV and 5.2 eV, which is favorable for hole injection, and it also has excellent mechanical flexibility and light transmittance.⁴⁷ The idea of improvement is to realize the separation of PEDOT and PSS, and there are usually two strategies. One is the addition of polar organic solvents, ionic liquids, or surfactants.^{48–50} Due to the different hydrophilicities and hydrophobicities of PEDOT and PSS, the forces between these additives are different, which reduces the Coulomb attraction between them, thereby realizing the phase separation of both. The second is the protonation of PSS by an acid,^{51,52} that is, $\text{PSS}^- + \text{H}^+ \rightarrow \text{PSSH}$. Neutral PSSH and positively charged PEDOT will lose their Coulomb force so that they are separated. Currently, the conductivity of PEDOT:PSS is increased to 4380 s cm^{-1} through concentrated sulfuric acid treatment, which is close to the conductivity of ITO

($\sim 5000 \text{ s cm}^{-1}$), but the conductivity of PEDOT:PSS needs to be strengthened.⁵³ Because of the excellent solution processability of PEDOT:PSS, it can be well compatible with the low-cost OLED solution preparation technology. PEDOT:PSS exhibits excellent flexibility, while PEDOT:PSS has the disadvantages of acidity and easy moisture absorption, which indicates that the stability of PEDOT:PSS is poor and needs to be further solved.

2.1.4 Combination electrodes. A composite electrode is a combination of two or more electrode materials that utilize the advantages of each electrode material to achieve an optimized comprehensive performance. For example, silver nanowires are rough, using PEDOT:PSS with excellent solution processability can not only fill the unevenness of the electrode to a certain extent, so as to reduce the roughness, but also enhance the electrical contact between nanowires.¹⁹ Copper nanowires are easily oxidized and have discontinuous conductive holes. A composite layer of the redox graphene electrode can not only effectively inhibit the oxidation of copper nanowires, but also provide continuous conductivity.⁵⁴ At present, graphene grown by CVD is not a complete single crystal, often with a small crystal size, discontinuous grain boundary and many defects. These defects are important sources of electron scattering, which will greatly reduce the conductivity of graphene. By combining a few one-dimensional silver nanowires to bridge these linear defects and fractures, more conductive channels are created, and the conductivity of graphene is greatly improved.⁵⁵ Graphene microplates have good solubility and can be doped into the conductive polymer PEDOT:PSS to form a solution-processable transparent electrode material. The final composite electrode can double the efficiency of OLEDs compared to that of traditional ITO electrodes.⁵⁶ In short, typically, one electrode is the primary electrode and the other is the auxiliary electrode to solve the existing problems and improve the related performance.

2.2 Injection layer

Typically, the device structures of solution-processed OLEDs include formal and inverted structures. The critical point in achieving all-solution OLEDs is the hole injection layer (HIL) and the electron injection layer (EIL), which are inserted between the electrodes and emission layers. As an eligible HIL or an EIL material, its role is to increase the injection of holes and electrons. For example, a large barrier exists between ITO and the hole transport layer (HTL), which makes it difficult to inject the holes. Ultraviolet oxygen (UVO) and plasma treatments are regarded as commonly used methods to improve the surface work function. We can also develop a HIL material with the HOMO larger than the HTL, resulting in a stepped charge injection. Specifically, this ultra-thin film may create a dipole layer at the interface of the metal/organic layer. Because of the dipole layer, the vacuum levels of the metal and the organic layer will shift and then the injection barrier will be decreased.^{57,58} In this section, solution-processed injection materials based on the two strategies described above are discussed.

2.2.1 HIL materials

Organic HIL materials. Hole injection materials consist of organic and inorganic compounds. Organic compounds in HIL materials can also be classified as small molecules, polymers and polymer-doped HIL materials.^{59–61} For solution-processed OLEDs, poly(3,4-ethyl-enedioxythiophene):poly(styrenesulfonic acid) (PEDOT:PSS) dispersed in an aqueous solvent is considered as a commonly used HIL material due to its suitable work function from 5.1 to 5.3 eV, especially for the formal structure of OLEDs. The use of PEDOT:PSS can modify the roughness of the ITO surface, reduce the turn-on voltage and increase the operational lifetime of the devices.^{62,63} However, the acidity and hygroscopicity of PEDOT:PSS may greatly affect the device stability^{64,65} and further result in some different issues, such as the diffusion of metal ions and chemical degradation of the emitting layer.^{66,67} To solve the above issues, Lee *et al.* blended a perfluorinated ionomer (PFI) into PEDOT:PSS and succeeded in forming a gradient PEDOT:PSS/PFI HIL with a ϕ_{WF} value from -5.2 eV to -5.95 eV (Fig. 1a). The formation of the spontaneous gradient HIL was attributed to the highly hydrophobic moiety in the PFI. In the process of the PEDOT:PSS/PFI layer, the PFI always moves towards the surface of the layer and then results in an uneven distribution of the PFI from the inside to the surface. As depicted in Fig. 1b and c, the prepared device based on this gradient HIL has achieved an optimal T_{50} of 2680 h at an initial brightness of 1000 cd m^{-2} , while 52 h for its original device.⁶⁸ In addition, the introduction of the alcohol-soluble PFI not only improved the hole injection but also provided the capability to form a high-quality film on the surface of the organic layer. To address the poor quality of the HIL film, Kido *et al.* introduced methanol (MeOH) and isopropanol (IPA) into a kind of PEDOT:PSS (Clevios CH8000), whose conductivity is relatively low.⁶⁹ As shown in Fig. 1d, Zhang *et al.* also used IPA in PH 1000 PEDOT:PSS with high conductivity and successfully prepared high-quality HIL film.⁷⁰ In addition to PEDOT:PSS, there are other promising polymer-doped HIL materials. For instance, Minarini *et al.* used a nanocomposite HIL layer of polyaniline:poly(styrene sulfonate) (PANI:PSS) to obtain a three times increase in the current efficiency.⁷¹ So *et al.* incorporated polythienothiophene (PTT) with poly(perfluoroethylene-perfluoroethersulfonic acid) (PFESA) to construct a compound HIL and the OLEDs exhibited a much longer lifetime compared with the devices using CuPc or PEDOT:PSS.⁷²

1,4,5,8,9,11-Hexaazatriphenylene hexacarbonitrile (HAT-CN) is a small molecule HIL material that is widely used in vacuum evaporation devices, especially used as a charge generation layer for laminated OLEDs. Lin *et al.* found that HAT-CN has strong selective solubility which makes it only dissolve in acetone but insoluble in commonly used solvents like chlorobenzene and toluene. By using acetone as the solvent of HATCN, a HIL layer with 4 nm thickness was fabricated, and the device performance was comparable to that of PEDOT:PSS OLEDs.⁵⁹ For small molecule HIL materials, Dan *et al.* blended two HTL materials, mCP and TCTA, and accomplished the preparation of green solution-processed phosphorescent OLEDs

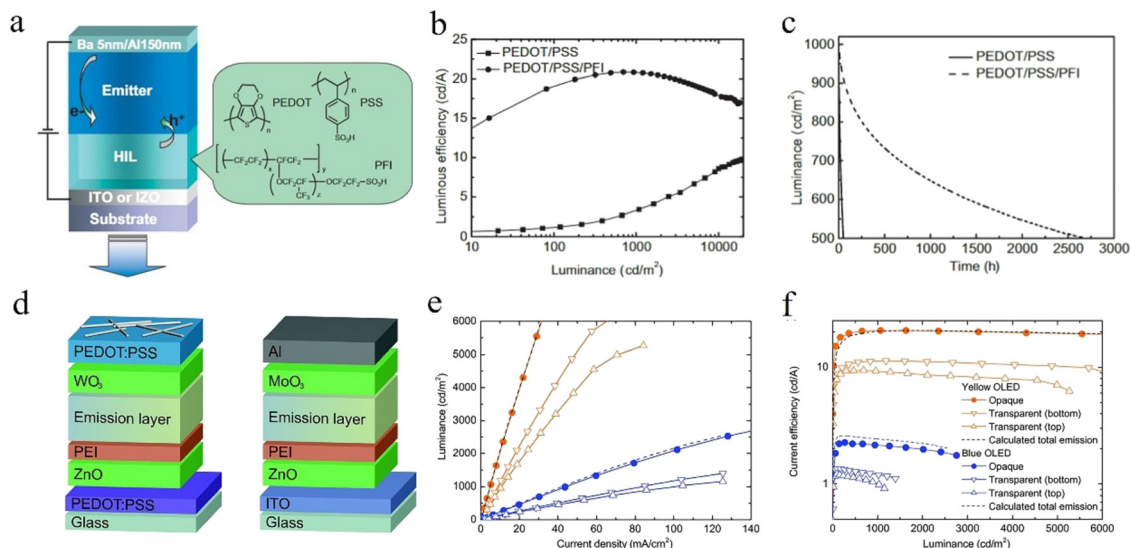


Fig. 1 (a) PLED device structure and the chemical structures of the components of conducting polymer compositions used for HILs. Device luminous efficiency and device lifetime: (b) Luminous efficiency versus luminance and (c) device lifetime with an initial luminance of 1000 cd m^{-2} for the devices using PEDOT/PSS and PEDOT/PSS/PFI as a HIL.⁶⁸ Copyright 2007 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (d) Device architectures of the all-solution processed TOLEDs comprising PEDOT:PSS bottom cathodes and PEDOT:PSS/AgNW top anodes and the opaque reference OLEDs. Optoelectronic characteristics of the yellow- and blue-emitting TOLEDs in comparison with those of the respective opaque reference devices. (e) Luminance vs. current density (L - J) and (f) current efficiency vs. luminance.⁷⁰ Copyright 2015 The Royal Society of Chemistry.

(PHOLEDs).⁷³ By mixing these two HTL materials, the drive voltage at 1000 cd m^{-2} was effectively reduced from 6.5 to 5.5 V. This hybrid strategy has successfully realized a novel type of hybrid material with better cavity, transport capacity and solubility resistance. Compared with the device with the single HIL of TCTA, the device with the combined HIL has a higher current efficiency (CE) and a lower turn-on voltage. As a result, the optimized device of the combined OLED showed a maximum CE and a power efficiency (PE) of 39.5 cd A^{-1} and 24.5 lm W^{-1} , respectively.

Inorganic HIL materials. Inorganic HIL materials such as metal oxide, metal sulfide and some other inorganic materials are also noted for the preparation of solution-processed OLEDs. Metal oxide always refers to the transition metal oxide (TMO), which includes the commonly used MoO_3 ,^{74,75} NiO_x ,^{76,77} WO_3 ,⁷⁸ and V_2O_5 ,^{79,80} and so on. As shown in Fig. 2a, these TMO HIL materials have a high value of ϕ_{WF} close to 7.0 eV, resulting in a deep conduction band (CB). In another word, its hole injection mechanism will be different from other HIL materials. To put it simply, the hole injection mechanism of TMO is that the HOMO electrons of the HTL will be extracted to the CB of TMO to realize an equivalent hole injection.⁸¹ There are two kinds of solution-processed TMOs, one is precursor solution and the other is nanoparticle dispersion. For the TMO precursor solution, researchers will choose different solvents for different solution-processed technologies. In general, a polar solvent such as isopropyl alcohol is chosen in order to achieve orthogonality with the solvent of the emitting layer (EML). MoO_3 is a commonly used HIL material in vacuum evaporation OLEDs with a ϕ_{WF} value, CB and valence band (VB)

of 6.7 eV, 6.9 eV and 9.7 eV, respectively. It has the advantages of low cost, strong hole injection ability and no corrosion to the ITO anode. Many studies have applied MoO_3 in the solution OLED through different solution synthesis methods. Liu *et al.* proposed a solution method. They first dissolved powder MoO_3 in ammonia water and then diluted it with deionized water. Finally, this kind of s- MoO_3 thin film showed better hole injection performance and reduced exciton quenching, thus improving the performance of the device.⁷⁴ Murase *et al.* pre-heated the MoO_3 precursor solution in deionized water before spin-coating, after which a very uniform and unbroken film was obtained.⁸² By utilizing the sol-gel method, Girotto *et al.* dissolved MoO_3 into H_2O_2 to form the $\text{MoO}_2(\text{OH})(\text{OOH})$ precursor solution.⁸³ TMO is susceptible for the preparation environment and the value of ϕ_{WF} may be dramatically cut from about 7.0 eV to about 5.0 eV by the polluted air, which has been verified by the research studies of Irfan *et al.* and Hancox *et al.* of MoO_3 ,⁸⁴ and V_2O_5 ,⁷⁶ respectively. Therefore, the value of ϕ_{WF} of solution-based TMO is always in the range of 5.3 to 5.7 eV. To repair the loss of ϕ_{WF} , Hammond *et al.* managed to increase the ϕ_{WF} value of MoO_3 from 5.0 to 6.1 eV by combining high temperature treatment under a vacuum environment and oxygen plasma treatment.⁸⁵

Copper thiocyanate (CuSCN) is a p-type semiconductor that is cheap and easy to be synthesized.^{47,86,87} TMOs and small molecule HAT-CN often require precise control for a few nanometers and an additional HTL which greatly limits their application prospect. But, for CuSCN , it has good air stability and a high hole mobility of $0.01\text{--}0.1 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$. Moreover, CuSCN can withstand the erosion of various organic solvents, which makes it better for the fabrication of laminated OLEDs,

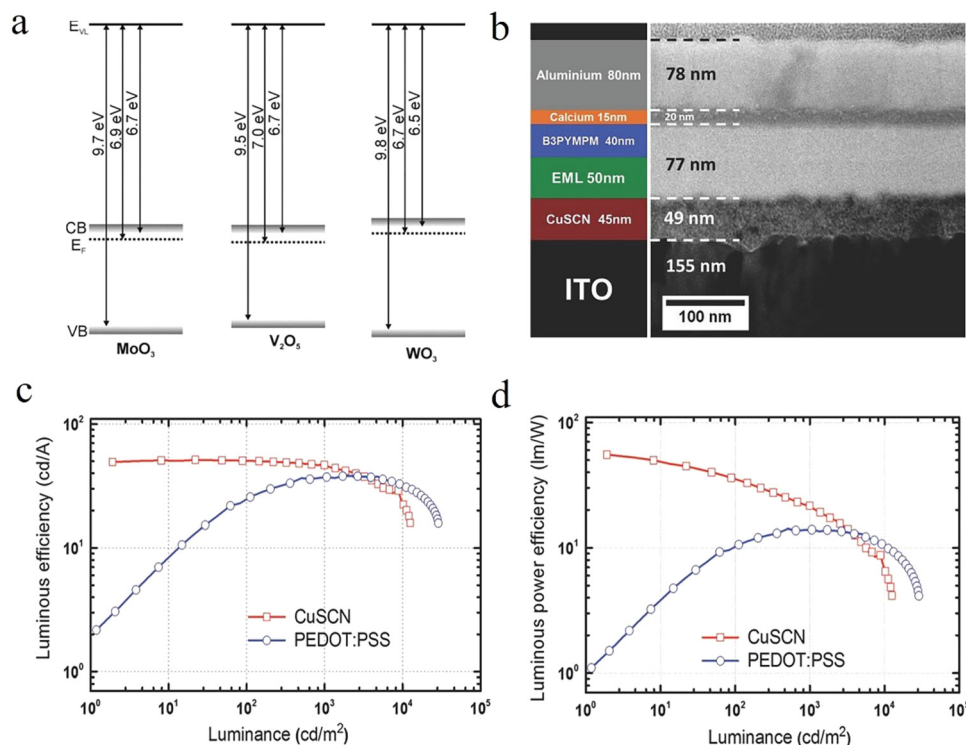


Fig. 2 (a) CB minimum and VB maximum with respect to the vacuum levels of MoO_3 , V_2O_5 and WO_3 .⁸¹ Copyright 2012 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (b) TEM image of the focused ion beam (FIB)-milled cross-section of a complete CuSCN HIL/HTL OLED (right side), together with a schematic of its stack structure (left side). The comparison of the OLED characteristics of CuSCN and PEDOT:PSS HIL/HTL structures. (c) Luminous efficiency (cd A^{-1}) versus luminance (cd m^{-2}) characteristics and (d) luminous power efficiency (lm W^{-1}) versus luminance (cd m^{-2}) characteristics of PEDOT:PSS (circles) and CuSCN (squares) structures.⁴⁷ Copyright 2014 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim.

and thus expands its application in OLEDs, OSCs and PSCs. Perumal *et al.* demonstrated a high-performance solution-processed green PHOLED by blending CuSCN HIL/HTL and the $(\text{PPy})_2\text{Ir}(\text{acac})\text{EML}$.⁴⁷ In their work, CuSCN-based devices showed a maximum luminance, CE and PE of over $10\,000\text{ cd m}^{-2}$, 50 cd A^{-1} and 55 lm W^{-1} (Fig. 2c and d).

2.2.2 EIL materials

Organic EIL materials. At present, metal cathodes with relatively high ϕ_{WF} and good air stability are commonly used in OLEDs, but the high value of the LUMO is not conducive for electron injection. To obtain highly efficient electron-injection, alkali metals with low ϕ_{WF} should be used as cathodes. However, these metals are too active, resulting in poor stability and difficulty in solution processing. To solve this problem, recently, a great breakthrough has been made in water-alcohol-soluble interfacial EIL materials. Using water/alcohol as the solvent, the destruction of the organic layer can be effectively avoided. In general, organic functional layers are insoluble in water/alcohol polar solvents. These materials can be divided into conjugated and non-conjugated polymers according to their molecular framework.⁸⁸

Based on the conjugated polymer, in 2004, Cao *et al.* first synthesized conjugated polymers poly[[9,9-bis(3'-(*N,N*-dimethylamino)-propyl)-2,7-fluorene]-*alt*-2,7-(9,9-dioctylfluorene)] (PFN) and used it as the EIL for PLEDs. They also found that even using a metal with high ϕ_{WF} as the cathode could obtain

high-performance solution-processed OLEDs.^{89,90} Since then, more and more research groups have carried out a series of modifications on the conjugated polymer PFN. For instance, poly[9,9-bis(60-(*N,N*-diethylamino)hexyl)-fluorene-*alt*-9,9-bis(3-ethyl-(oxetane-3-ethoxy)-hexyl)-fluorene] (PFN-OX)⁹¹⁻⁹³ and poly[9,9-bis(6-(*N,N*-diethylamino)propyl)fluorene-*alt*-9,9-bis(hex-5-en-1-yl)-fluorene] (PFN-V)⁹⁴ with a crosslinking characteristic can achieve highly efficient inverted OLEDs, while poly[[9,9-bis(3'-(*N,N*-dimethylamino)propyl)-2,7-fluorene]-*alt*-5,5'-bis(2,2'-thiophene)-2,6-naphthalene-1,4,5,8-tetracarboxylic-*N,N'*-di(2-ethylhexyl)imide] (PFN-2TNDI)^{95,96} with a high electron mobility can reduce the sensitivity of the thickness of the EIL. WOLEDs with an inverted structure prepared by solution methods have attracted more and more attention. However, for the ITO cathode and the metal anode, if ZnO is used as the electron transport layer (ETL), the charge injection potential barrier will be too high. To overcome this issue, Zhang *et al.* used modified PFN-OX, a novel cross-linked polymer, as the EIL modification layer. The CE and PE of their prepared devices were 18.8 cd A^{-1} and 6.7 lm W^{-1} , respectively (Fig. 3).⁹¹ Hwang *et al.* used cross-linked poly(FA90-*co*-BFA10) as the HIL, a solution-processable red phosphorescent OLED that exhibited a low turn-on voltage of 3.5 V, a reasonably high CE of 16.6 cd A^{-1} , and an EQE of 12.5%, all of which are superior to the corresponding reference device using PEDOT:PSS as the HIL.⁹⁷ Xue *et al.* were successful in preparing high-efficiency

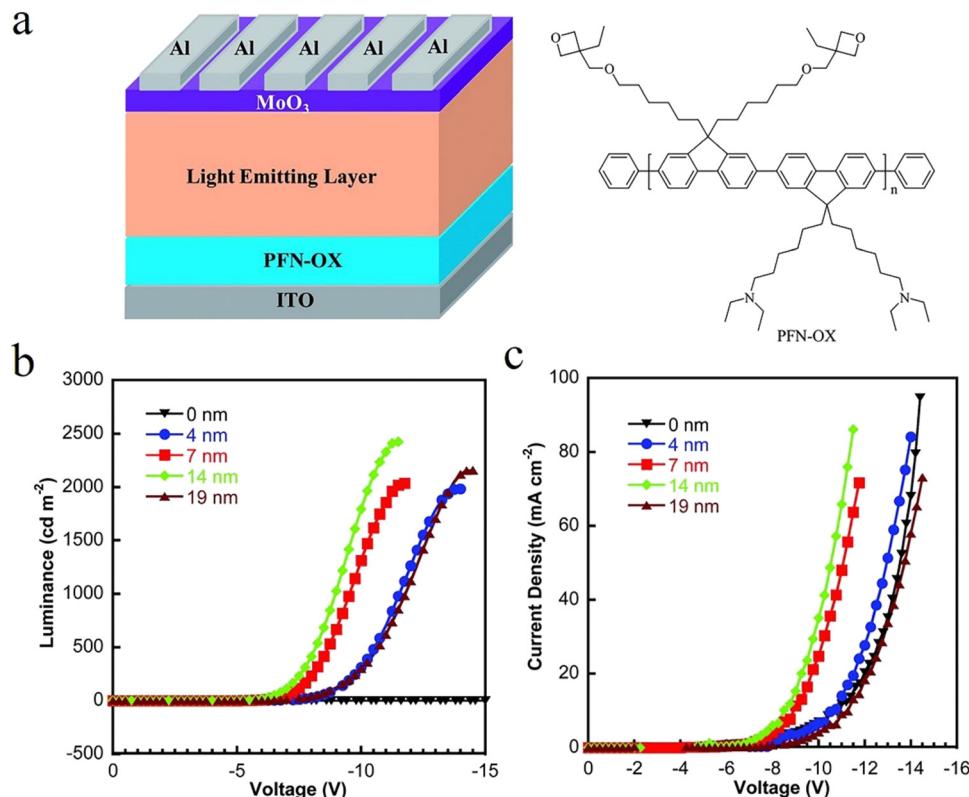


Fig. 3 (a) The device configuration of the inverted OLED and the chemical structures of PFN-OX and light emitting layer materials used in this study. (b) L - V and (c) J - V curves of blue light devices with different thicknesses of the PFN-OX interlayer.⁹¹ Copyright 2014 The Royal Society of Chemistry.

polymer WOLEDs by using three small molecule luminescent materials of red, green and blue.⁹⁸ In this work, they used poly[9,9-bis(2-(2-(2-diolamino ethoxy)ethoxy)ethyl) fluorene] (PF-OH) as the EIL to increase the CE of the original device from 9.2 cd A^{-1} to 20.7 cd A^{-1} and the turn-on voltage was reduced from 6.7 V to 4.5 V. Moreover, they further blended Li_2CO_3 into the conjugated polymer PF-OH to build up an n-type EIL/ETL. Consequently, their prepared Ph-WOLED has exhibited an optimal CE and PE of 36.1 cd A^{-1} and 23.4 lm W^{-1} , respectively. With respect to non-conjugated polymer EIL materials, in 2012, polyethylenimine ethoxylated (PEIE) and PEI were reported by Bernard *et al.* Compared with the conjugated polymer like PFN, it is necessary for them to pay more attention to the thickness control of the EIL but also this class of materials can introduce a stronger interface dipole, which can effectively reduce the ϕ_{WF} of the electrode and achieve more efficient electron-injection.⁴¹

Inorganic EIL materials. Compared with organic EIL materials, inorganic EIL materials show better stability and resistance to solvent erosion. In particular, for ZnO EIL, it is widely used in all-solution-processed OSCs and QLEDs.^{99,100} As mentioned above, when using ZnO as the EIL material in OLEDs, it can provide effective electron-injection only when the EML material has a deep LUMO. However, the LUMO energy level of most organic materials is always located in the range of -2.0 to -3.0 eV , which greatly limits the application of inorganic EIL

materials in the OLED field. Taking the aforementioned issue into consideration, Cao *et al.* prepared highly efficient all-solution-processed OLEDs by combining the merit of more effective electron-injection in the organic EIL with the merit of being erosion-proof in the inorganic EIL. In their work, they have designed a novel organic/inorganic hybrid PFN-OX/ZnO EIL. In contrast with the non-hybrid PFN-OX EIL, the hybrid EIL device demonstrated higher efficiency and lower switch-on voltage when using silver paste as the cathode (Fig. 4).¹⁰¹ They also designed a “solvent detector” so as to quantitatively study the ability of the resist dissolution of the PFN-OX/ZnO EIL. The change of the transverse conductivity of PEDOT:PSS is used to judge whether the solvent has been penetrated by the upper layer. As a result, the transverse conductivity of PEDOT:PSS did not change, indicating that the hybrid PFN-OX/ZnO EIL can completely prevent the downward infiltration of triethylene glycol monomethyl ether (TGME) solvent, and thus effectively protect the organic EML. Finally, the prepared all-solution-processed blue emission device can reach a maximum CE of 2.5 cd A^{-1} at 6.4 V. Besides, there are many other promising inorganic EIL materials, such as cesium stearate¹⁰² and Cs_2CO_3 ,^{103,104} which can also be converted for the solution-processed EIL.

2.3 Transport layer

2.3.1 HTL materials. In OLEDs, holes and electrons are injected into the EML from both ends, respectively; the HTL

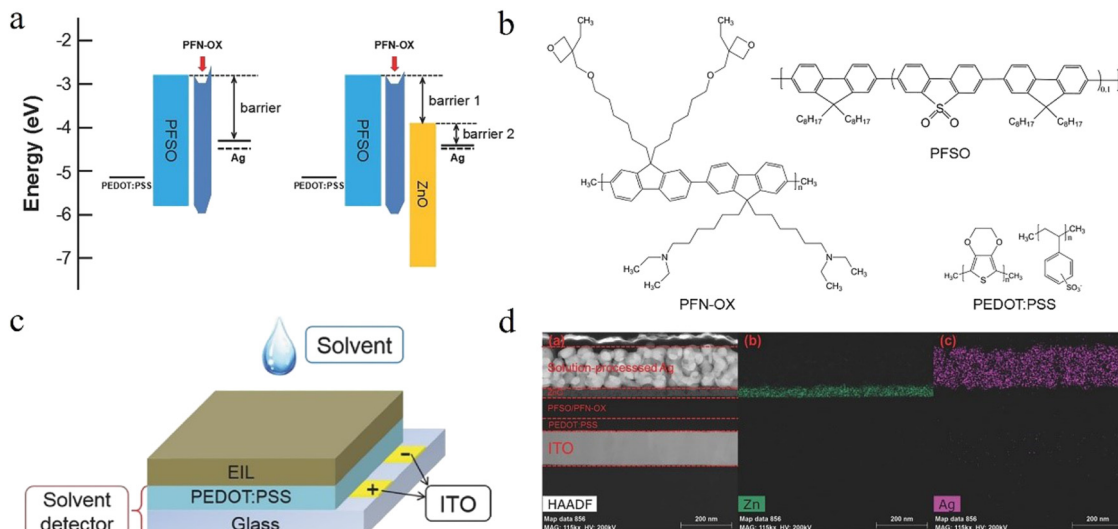


Fig. 4 (a) Energy level diagrams of the device. (b) Chemical structures of PFSO, PFN-OX, and PEDOT:PSS. (c) Schematic illustration of the "solvent detector." (d) EDS map of the all-solution-processed OLED.¹⁰¹ Copyright 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim.

mainly plays a role in promoting hole transport, which has an electron-donating part to form stable cation radicals. Materials with phenylamine groups have attracted much attention due to their high hole mobility and are mostly soluble in organic solvents. But some of these materials have low glass transition temperatures (T_g), which will also affect the stability of the morphology,^{105,106} thereby affecting the overall performance of the device. For example, the T_g of N,N' -di-[(1-naphthalenyl)- N,N' -diphenyl]-1,1'-biphenyl-4,4'-diamine (NPB) and that of N,N' -bis(3-methylphenyl)- N,N' -diphenyl-benzidine (TPD) are 96 °C and 65 °C, respectively. Their hole mobility is about 10^{-3} cm² V⁻¹ s⁻¹, which is also widely used in some devices.^{107,108} However, it is inevitable to find that the film surface is uneven and has high roughness due to high temperature. In response to these problems, some literature studies have also proposed new methods, such as adding TPD to poly(methyl methacrylate) (PMMA), PS, polysulfone, polycarbonate, *etc.* This mixed system can inhibit crystallization.¹⁰⁹ However, due to the existence of phase separation, this intercalation system cannot guarantee the stability of the morphology. In order to prevent degradation caused by crystallization, amorphous materials with high T_g can also be used to prepare morphologically stable and high-quality films. In addition to simply modifying molecules on TPD scaffolds by means of substitution, bridging and ring bonding, different structural modes can be studied to meet specific needs. Because spiro-linkage can change the steric requirements of low-molecular organic compounds to improve their morphological stability, Bestgen *et al.* synthesized and designed the HTL material spiro-TAD based on spiro compounds.¹¹⁰ The spiro-TAD has high T_g and can prepare high-quality films with high morphological stability through spin coating technology. Ultimately, they fabricated blue-light devices with high brightness, high color purity, and low V_{on} .

Another way to obtain stable films is to use starburst hole transport materials based on the TDATA and TDAPB families.

For example, m-MTDATA and 2-TNATA have been used as HTL materials in many works and played an important role.¹¹¹ m-MTDATA and its analogs have extremely low solid-state ionization sites (5.0–5.1 eV) and are reversibly anodized to generate stable cationic radicals.¹¹² In addition, spin-coated amorphous films using this material have very good film quality.

Compared with TDATA, TDAPB is resistant to crystallization due to its high T_g and steric hindrance by the four central phenyl groups. At the same time, because of its high solubility, it is more convenient for solution preparation. Wehrmann *et al.* added TDAPB between the HIL and EML.⁶² By comparing the device characteristics and working life with the device without TDAPB, it was proved that the addition of TDAPB can not only prepare high-efficiency devices, but also prolong device lifetimes.

Chae *et al.* used TCTA with good film formation and solubility as the HTL material for green Ph-OLEDs.¹⁰⁵ TCTA can be prepared by both spin coating and vacuum evaporation, but the surface roughness of the TCTA films obtained by the two methods is different, which is mainly due to solvent evaporation during spin coating. TCTA can form a good amorphous film mainly due to its three-dimensional structure. TCTA has two coplanar carbazole units, one of which is perpendicular to the plane containing the two carbazole units, which is conducive to the formation of amorphous molecular packing. Ultimately, they successfully fabricated green PHOLEDs with efficiencies of 33.7 cd A⁻¹ and 19.6 lm W⁻¹, respectively.

Periasamy *et al.* designed and synthesized two HTL materials, DHABS and DPABS;¹¹³ their HOMOs are comparable to the widely used TPD, although the device performance based on these two HTL materials is not as good as the TPD-based device, but also provides us with new ideas. Kido *et al.* used a-NPD as the HTL material and 10 wt% TBPAAH doped with DFPA2 as the hole injection buffer layer,¹¹⁴ finally obtained a

device with low V_{on} and high PE. Taniguchi *et al.* designed and synthesized a new thermally stable HTL material T-Caz,¹¹⁵ which has an extremely high T_g of 250 °C. Based on this HTL material, a green device with a maximum brightness of 10300 cd m⁻² was finally prepared.

A new small molecule thermally cross-linked material PbV was synthesized by Ha *et al.* This newly synthesized HTM has almost no pinholes after the cross-linking reaction and can form very uniform films. The corresponding red phosphorescent OLED showed a CE of about 16.7 cd A⁻¹ and an EQE of 12.4%.¹¹⁶ Thermal cross-linked materials E-TPD were designed and synthesized by Peng *et al.* The corresponding solution-processed green phosphorescent OLED obtained excellent performance with a V_{on} of 3.3 V, a CE_{max} of 60.74 cd A⁻¹, and an EQE_{max} of 17.33%.¹¹⁷

2.3.2 ETL materials. The role of the ETL is mainly to facilitate the efficient injection of electrons from the cathode into the organic layer, transport electrons, and inhibit the transfer of holes to the cathode, which is crucial for improving the efficiency and stability of the device. Therefore, the ETL material molecules need to have electron acceptor groups to form stable anion free radicals.

Currently, PBD is commonly used in the ETL, but PBD also has defects. For example, it is a crystalline material, and it is also very easy to crystallize at room temperature. Therefore, in order to obtain stable amorphous ETL materials, scientists have also synthesized PBD-based spiro, branched derivatives and starburst dendrimers, which are widely used in OLEDs.

Besides PBD, triazole and benzimidazole derivatives are also commonly used ETL materials, such as TPBi and TAZ, which can not only facilitate electron transport but also better block excitons. TPBi also has the characteristics of high solubility in alcohol solvents, which also makes TPBi play an important role in the preparation of OLEDs by solution methods.¹¹⁸ Taniguchi *et al.* synthesized novel amorphous ETL materials phenoxy-TPBi with benzimidazole,¹¹⁹ both of which have high T_g (= 108 to 110 °C) and thermal stability, and are easily soluble in common organic solvents such as acetone and tetrahydrofuran. Devices based on these two ETL materials show no emission phenomenon, but carrier transport properties can be observed (400 mA cm⁻²).

In addition to the above, pyridine-based derivatives are also outstanding among ETL materials for OLEDs.¹²⁰ The reported electron mobility of TMPPB is as high as 7.9×10^{-3} cm² V⁻¹ s⁻¹, which is also very shocking data.¹²¹ Petty *et al.* developed a series of ETL materials based on two oxadiazole derivatives and three oxadiazole novel-containing pyridine units. They mixed these materials with MEH-PPV and carefully studied the effect of ETL thickness and annealing on the device. Their results showed that oxadiazole molecules containing pyridine units were more stable than those containing benzene rings alone.

Although many amorphous ETL materials have good solubility, they are often used in solution preparation to prepare smooth, flat and stable films. However, in most of the work, in order to prevent the light-emitting layer from being dissolved, the vacuum deposition method is chosen to prepare the ETL.

There is still a long way to go to study ETL materials in order to simplify the process of solution preparation, reduce the cost of device preparation and accelerate the commercialization of OLEDs.

2.4 Emitting layer

Printed OLED emitting materials mainly include organic small molecule materials (phosphorescent materials, fluorescent materials, and TADF materials) and polymer materials, which play a very important role in the performance of devices. Generally, if the small molecule emitting materials used in the traditional evaporation process are directly applied to the printing process, the performance of the device will be seriously affected due to its low solubility and poor film-forming effect. The development of new printed OLED emitting materials not only needs to pay attention to their luminescence efficiency, film-forming properties, stability, color purity and cost, but also needs to focus on the materials themselves to match the printing process.

2.4.1 Small molecule based emitting materials. In recent years, solution-based small molecule OLEDs have attracted more and more research attention, because this technology combines the advantages of easy synthesis of small molecules and the advantages of low-cost polymers. There are usually two methods to prepare devices: evaporation and solution methods. For small molecular materials, the standard preparation method is vacuum vapor deposition; For polymer materials, simple solution processes can be used, such as spin coating or inkjet printing. Small molecules have the advantages of easy synthesis and purification. Vapor deposition technology can prepare complex multilayers with excellent device properties. However, the thermal evaporation process under high vacuum increases the manufacturing complexity and makes the utilization rate of expensive OLED materials very low (20%). Most of the small molecules used in vacuum deposition are not suitable for the solution process because of their poor film morphology and being easy to crystallize after spin casting.

From the development history of emitting materials, the first generation of luminescent materials is fluorescent molecules represented by Alq₃, which are gradually replaced (<25%) due to the limitation of an internal quantum efficiency (Fig. 5a).^{122–125} These devices are generally inefficient and cannot meet the application requirements.

To break through this limitation, PHOLEDs with an internal quantum efficiency of nearly 100% have been developed (Fig. 5b).^{126–129} Phosphorescent materials are mainly divided into pure organic phosphorescent materials and complex phosphorescent materials with heavy metals as the core. Pure organic phosphorescent materials have high flexibility, low cost, environmental protection and other application potential, but their performance is still poor. Therefore, the OLED technology of complex phosphorescent materials is more popular at present. In order to achieve appropriate solubility and inhibit the self-quenching effect and triplet-triplet annihilation effect, small molecule phosphorescent materials usually obtain high quantum efficiency by matching with the polymer host

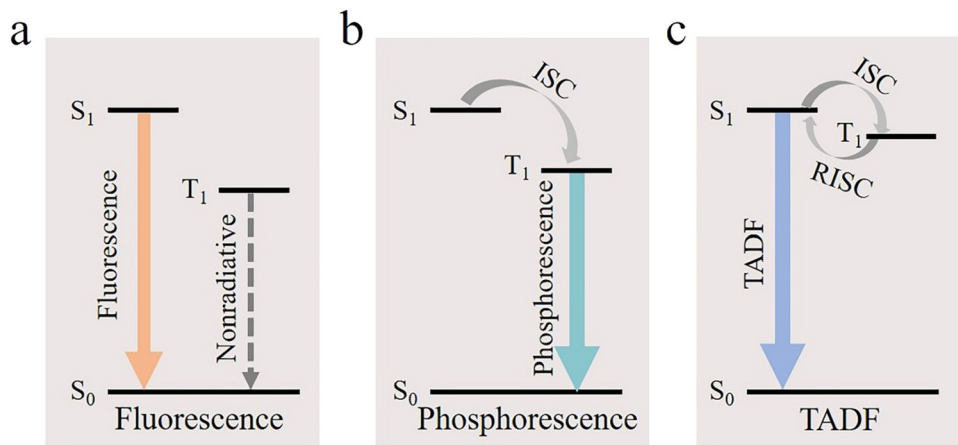


Fig. 5 Mechanism of (a) fluorescent, (b) phosphorescent, and (c) TADF materials.

or doping hole transport materials. In 2019, Xing *et al.* investigated the inkjet-printed OLEDs of Ir(mppy)₃ with a mixture of m-MTDATA and TPBi as the co-host and obtained a maximum brightness of 13 240 cd m⁻².¹³⁰ In 2020, Mu *et al.* successfully prepared a binary phosphorescent small molecule material based on Ir(MDQ)₂(acac). The maximum current efficiency produced by the ink-jet printed PHOLED was 17.89 cd A⁻¹.¹³¹ Zhang *et al.* reported a doping method of blending a small molecule phosphorescent material with a transmission material. The maximum brightness of the prepared green phosphorescent device reached 40 320 cd m⁻², the maximum current efficiency reached 40.9 cd A⁻¹, and color coordinates are (0.300, 0.630).¹³² Dpan-5bzac, a bipolar transport material with high triplet energy, was mixed with hole transport materials MCP and TCTA as the main body of ternary blending. Combined with the typical iridium coordinated phosphorescent material Ir(PPy)₂acac, the excellent miscibility and ordered structure of the light-emitting layer were realized, and the transport balance of carriers was enhanced.

In recent years, thermally activated delayed fluorescence (TADF) has also been used to improve the efficiency of OLEDs. In the TADF mechanism, the triplet state is converted to the singlet state by reverse intersystem crossing (RISC) to obtain 100% of excitons generated by electrical excitation in the device (Fig. 5c).^{133–137} In 2016, Verma *et al.* realized the TADF-OLED by ink-jet printing for the first time. The CE of the OLED reached 45 cd A⁻¹, and the EQE was 13.9% ± 1.9%.¹³⁸ In 2019, Amruth *et al.* investigated and optimized the TADF material tBuG2TAZ in printed OLEDs. The prepared devices realized a maximum CE of 18.0 cd A⁻¹ and a maximum brightness of 6900 cd m⁻².¹³⁹ OLEDs with TADF as the main material have many advantages, such as low driving voltage, high efficiency, long lifetime and low efficiency roll-off. However, due to its poor solubility, there are still many challenges in the preparation of inkjet printing.

2.4.2 Polymer based emitting materials. The ability of polymers to form excellent films in the solution process has been known. Compared with organic small molecular materials, polymer materials are easy to process and modify, are more

suitable for printing OLEDs, and have broad application prospects. Fluorene derivatives have some advantages of wide band gap, easy processing, strong fluorescence quantum efficiency and spectral stability. They are the most common blue light conjugated polymerization units. Hu *et al.* reported a polymer PFSO10TA, which introduced *S,S*-dioxo-dibenzo-thiophene (SO) into the main chain of polyfluorene and terminated with triphenylamine (TA) to inhibit intramolecular charge transfer and enhance luminescence efficiency. Using the polymer PFSO10TA as the emitting layer, after annealing at 115 °C, the CE_{max} of the device reaches 7.3 cd A⁻¹, the maximum brightness is 14 882 cd m⁻², and the color coordinates are (0.160, 0.150).¹⁴⁰ Zhang *et al.* embedded a small amount of 2,5-dimethyl-1,4-*p*-phenylene units in the polyfluorene skeleton to synthesize PFDPN. Structurally, PFDPN inserts flexible units into the main chain of polyfluorene, resulting in a disordered conformation during film formation, increasing its radiation attenuation rate, and finally improving the electrical and optical properties of the device.

Similar to TADF small molecular materials, the design of TADF polymer materials also requires the construction of a small enough energy gap to achieve a fast RISC process. Shao *et al.* reported a molecular design strategy of the non-conjugated TADF blue photopolymer for solution treatment, and synthesized the polymer P-Ac-TRZ.¹⁴¹ The spatial gap between polyethylene and the acceptor is high, so that the side chain of polyethylene can not only be separated from the acceptor, but also the side chain of the acceptor can be separated, so that the side chain of polyethylene can be separated from the acceptor. Finally, the EQE_{max} of the device made of the polymer material reached 12.10%, and the color coordinates are (0.176, 0.269). In addition, dendritic macromolecular materials, which integrate the advantages of small molecular materials and polymer materials, have also attracted extensive attention as luminescent materials for printed OLEDs. The unique dendritic branch structure not only forms a certain steric hindrance, but also makes the material soluble and amorphous and has good thermal stability through flexible modification.¹⁴²

3. Device structure

At present, in most vacuum-deposited OLEDs, the multi-layer structure is more beneficial to realize high efficiency and long lifetime. This is mainly because it can more precisely control the injection and transport of carriers, the formation and distribution of excitons, and the energy transfer between the host and the object.¹⁴³ At the same time, since each layer of vacuum-deposited OLEDs is sequentially deposited under vacuum, the film coverage of each layer is uniform and flat, and the function of other layers will not be affected. Compared with vacuum-deposited OLEDs, solution-processed OLEDs are difficult to prepare multi-layer structures due to the possible problems of interdiffusion and compatibility between layers. The performance of solution-processed OLEDs will be even better with using cross-linked materials and orthogonal solvent strategies.^{144–146} Although some scientists have been studying and synthesizing new functional materials in order to realize ideal multi-layer solution-processed OLEDs,¹⁴⁷ more work has been focused on exploring solution-processed OLEDs with a simpler structure or employing a hybrid procedure of the solution process and vacuum deposition.¹⁴⁸ In this hybrid structure, the EML is generally prepared by solution methods, and the electron buffer layer (EBL) and the ETL are prepared by the vacuum deposition method. This method is suitable for PHOLEDs, which can prolong the lifetime of triplet excitons. Excellent performance can be achieved by confining triplet excitons in the EML *via* adding the EBL.

To meet the goal of commercialization, reducing the preparation cost is the top priority of solution-processed OLEDs, but at the same time, it is necessary to ensure that the efficiency and life of devices are not affected. Therefore, the solution process needs to meet the following requirements: (1) use efficient, low-cost, and stable materials for each layer as much as possible, and each layer cannot interfere with each other, which can synergistically extend the device life of solution-processed OLEDs. (2) Each layer should be prepared by solution

methods as much as possible, using orthogonal solvents as far as possible and ensure that the film formation of each layer is smooth and uniform at the same time. (3) The device structure is as simple as possible, thereby reducing production costs and processes. (4) The energy level matching material is used to reduce the energy level barrier, which is beneficial to charge carrier injection and transport.

3.1 Basic device structure

Firstly, some typical device structures of solution-processed OLEDs and the corresponding fabrication methods are introduced. As shown in Fig. 6a, it is the simplest device structure of solution-processed OLEDs, consisting of only two films prepared by solution methods. PEDOT:PSS is commonly used as the HIL. For the cathode, different metal electrodes are also used in different works. Wang *et al.* successfully prepared a device with a brightness of $11\,900\text{ cd m}^{-2}$ using Ca/Al as the electrode.¹⁴⁹ Cao *et al.*¹⁵⁰ and Kido *et al.*¹⁵¹ used Ba/Al and Mg:Ag to prepare different devices, respectively. The devices with the simplest structure have made a great contribution to the industrial preparation of large-scale OLEDs in terms of reducing the cost and the preparation process,^{152,153} and also promoted the large-scale manufacturing of solution-processed OLEDs. However, due to the small number of layers, the optimization of each layer is particularly important. Wong *et al.* used low-conductivity PEDOT:PSS as the anode buffer layer of the device, and further optimized the EML, finally obtained a device with an EQE_{max} of 28.8% and a CE_{max} exceeding 60 cd A^{-1} .¹⁵⁴ Instead of using the traditional two-layer cathode (BaF₂/Al and Ba/Al), chin *et al.* used a novel three-layer cathode (BaF₂/Ca/Al) which greatly improved the lifetime of the device.¹⁵⁵ At the same time, the influence of the thickness of BaF₂ on the device performance was studied. As shown in Fig. 7, when the thickness of BaF₂ is less than 3 nm, Ca will be in direct contact with the EML, which will cause the luminescence quenching of Ca, and will also reduce the

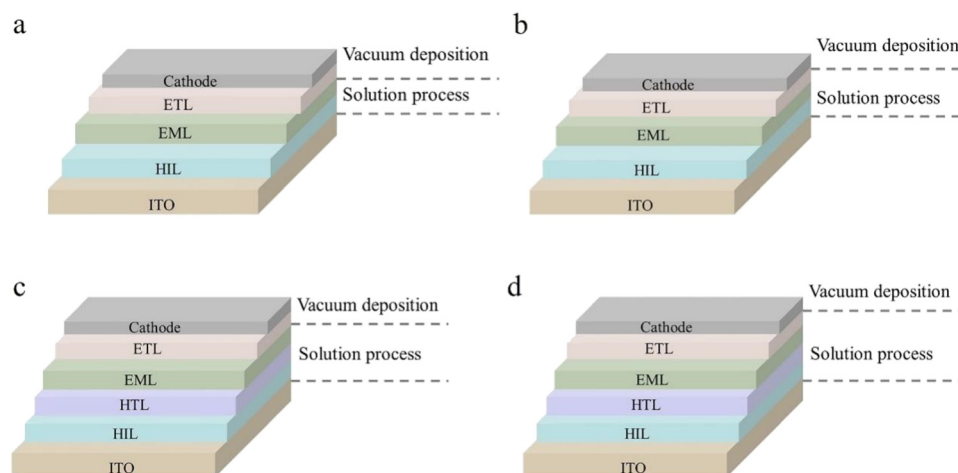


Fig. 6 Basic device structures and processing method of solution-processed OLEDs with (a) solution-processed HIL/EML, (b) solution-processed HIL/EML/ETL, (c) HIL/HTL/EML, and (d) HIL/HTL/EML/ETL, respectively.

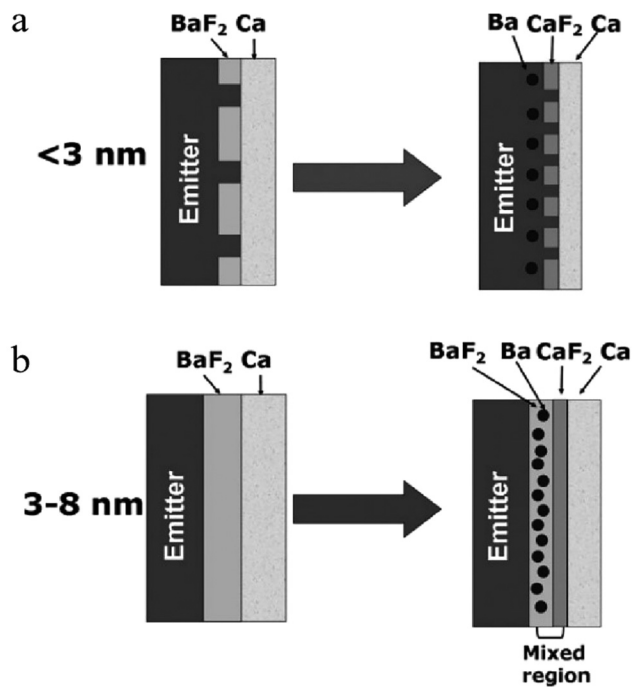


Fig. 7 Schematic diagrams of the contact between the cathode ($\text{BaF}_2/\text{Ca}/\text{Al}$) and the emitter for (a) a thin BaF_2 layer with a thickness less than 3 nm, and (b) a BaF_2 layer with a thickness of 3–8 nm.¹⁵⁵ Copyright 2009 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim.

lifetime of the device. In contrast, if a BaF_2 layer of 3–8 nm is used, the direct contact of Ca with the EML can be avoided. There will be a CaF_2 layer or a mixed layer of BaF_2 and CaF_2 , which is beneficial to the injection and transport of carriers. In addition, there are also some works to add some buffer layers between the EML and the cathode to prolong the lifetime of the device during operation.^{156–158}

As shown in Fig. 6b, a vacuum-deposited ETL is added between the EML and the cathode, which can promote the injection and transmission of electrons. Meanwhile, the use of an ETL with a suitable energy level can confine the excitons in the EML,¹⁵⁹ which can increase the utilization of excitons,

thereby improving the efficiency of solution-processed OLEDs. Wang *et al.* prepared high-efficiency solution-processed deep-blue and white OLEDs with FIR_6 as the blue material and PVK as the host.¹⁵⁹ In addition, they added an interface layer with a higher triplet energy level between the EML and the ETL, which can effectively inhibit the transfer of excitons from the EML to the ETL, thereby reducing the energy loss of excitons. It can also improve the performance and prolong the work lifetime of devices. Finally, the deep-blue OLED achieved an EQE, a CE and a PE of 16.1%, 31.5 cd A^{-1} and 15.1 lm W^{-1} , respectively. Besides, white OLEDs achieved a high total EQE and a PE of 28.0% and 38.4 lm W^{-1} , respectively. This work further demonstrated the importance of reducing triplet exciton loss at the interfaces. Similarly, Wang *et al.* also used a high-energy-level blue phosphorescent material FIR-p-OC_8 in the EML to prepare solution-processed WOLEDs with an efficiency comparable to that of fluorescent tubes.¹⁶⁰ FIR-p-OC_8 not only achieved efficient blue emission, but also enhanced the HOMO/LUMO levels to match the dendritic host H_2 well. At the same time, as shown in Fig. 8, the direct formation of excitons on the blue phosphorescent material can reduce the turn-on voltage and improve the power efficiency. The PE_{max} of WOLEDs based on FIR-p-OC_8 reached 68.5 lm W^{-1} , which decreases slightly to 47.0 lm W^{-1} at a brightness of 1000 cd m^{-2} . By introducing light extraction technology, the efficiency can be further improved to 96.3 lm W^{-1} at a brightness of 1000 cd m^{-2} . Their results can compete with commercial fluorescent tubes with a good level of reference.

In OLEDs, the optimization of the transport layer is extremely important because the mobilities of electrons and holes in the corresponding transport layers differ by 1–2 orders of magnitude. Although the commonly used PEDOT:PSS has been widely used,^{161–163} its shortcomings cannot be ignored. For example, PEDOT will corrode the ITO substrate, resulting in the diffusion of the anode metal to the EML,⁶⁸ which will seriously affect the performance of the device. In addition, the energy level gap will also weaken the hole injection ability.^{67,164} To address these issues, the HTL can be further added to the HIL and the EML, as shown in Fig. 6c. During operation,

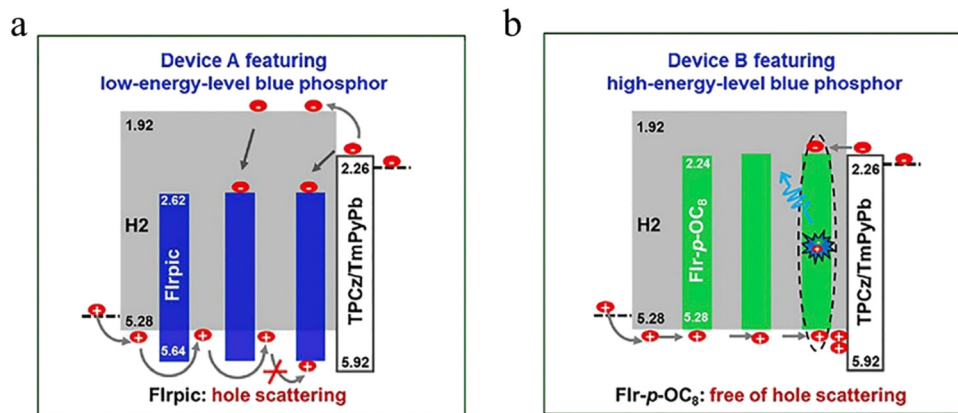


Fig. 8 Effect analysis of hole scattering. (a) Working mechanism of the FIRpic -based blue device. (b) Working mechanism of the FIR-p-OC_8 -based blue device.¹⁶⁰ Copyright 2018 Elsevier.

layer-to-layer interactions should also be avoided. Chen *et al.* just considered that exciton quenching at the interface between PEDOT:PSS and EML would affect the efficiency and lifetime of the device,¹⁴⁷ so they introduced a cross-linkable HTL material Ox-DCDPA, achieved solution-processed green and bluish-green OLEDs with efficiencies of 26.1%/94.8 cd A⁻¹ and 24.0%/74.0 cd A⁻¹, respectively. By further adding another material (X-DCDPA) and Ox-DCDPA to form a double HTL structure, green and bluish-green OLEDs with efficiencies of 30.8%/111.9 cd A⁻¹ and 27.2%/83.8 cd A⁻¹, respectively, were finally obtained.

The structure shown in Fig. 6d is the device structure prepared by the solution method except the anode and the cathode. At present, many works using this structure have also achieved good results. Wang *et al.* successfully fabricated a multi-layer green OLED with an EQE of 21.2% and a CE of 68.4 cd A⁻¹ by the layer-by-layer solution method of orthogonal solvents using the self-host dendrimers as non-EML materials.¹⁴⁶ The efficiency of the device is comparable to that of the doped device, and it also avoided the problem of layer-to-layer dissolution, which is also beneficial for the reproducibility of the experiment. Similarly, Kido *et al.* demonstrated that small host molecules based on covalent dimerization or trimerization instead of polymerization were sufficiently resistant to the alcohol used to process the upper layer under solvent resistance tests for small host molecules,¹⁶⁵ thereby preparing a series of blue, green and white high-efficiency solution-processed multilayer OLEDs with record PE_{max} of 36, 52 and 34 lm W⁻¹ at 100 cd m⁻², respectively. Their work also showed that the composition at the interface of the solution-processed layer is a key factor in determining device performance.

In addition to the above-mentioned cases that only the functional layers were processed by the solution method, the devices can be fabricated by solution methods for all functional layers including electrodes. This kind of all-solution structure is expected to further reduce the preparation cost, and the main challenge is to realize the solution preparation of the injection layer/electrode interface. Cao *et al.* achieved all-solution preparation by inkjet printing nanoscale silver particles on the buffer layer to uniformly fabricate the cathode using epoxy adhesive and a novel water-/alcohol-soluble conjugated polyfluorene polyelectrolyte PFNR₂ as the buffer layer.¹⁶⁶ A 1.5 inch display device is shown in Fig. 9a. The working principle of the buffer layer is that after the epoxy adhesive is cured, a stable three-dimensional copolymer network is formed by cross-linking, preventing the intrusion of organic solvents. Water-soluble conjugated polymers provide good film-forming ability, necessary electron injection ability, and the modulation of surface energy to match the printed cathode. The resulting 1.5 inch polymer light-emitting diode display was manufactured without any dead pixels. This process solved the problem of high vacuum for the thermal evaporation of the cathode and paved the way for the manufacture of the flat panel display in industry. In the following work, they combined the advantages of organic and inorganic EILs to prepare an all-solution-processed OLED with an efficiency of 2.1 cd A⁻¹ using a novel hybrid EIL (PFN-OX/ZnO) and

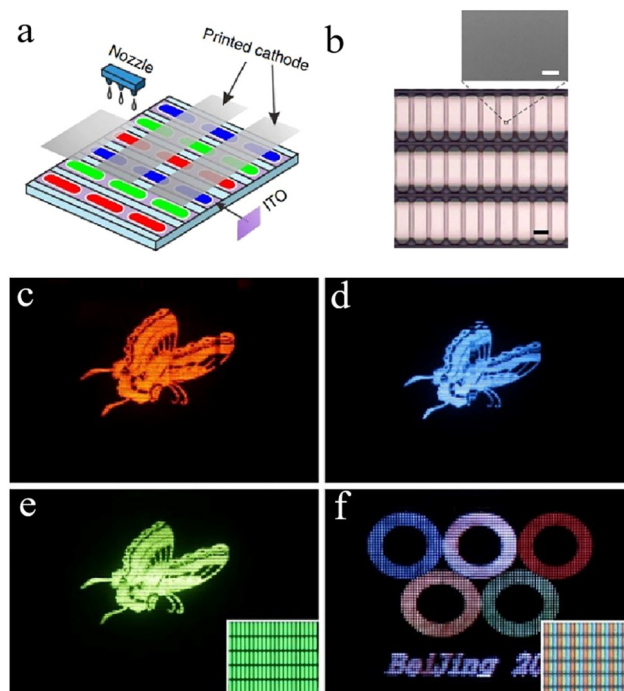


Fig. 9 Device structures and photographs of monochrome and full-color displays. (a) Schematic of the full color structure. (b) Microscopic image of the back of the display. (c) Red, (d) blue and (e) green monochrome displays. (f) Full-color display with a microscopic image.¹⁶⁶ Copyright 2013, Nature Publishing Group.

spin-coated silver nanoparticles as cathodes.¹⁰¹ This hybrid EIL not only exhibited better electron injection, but also retained the solvent resistance of inorganic EILs. In addition to using silver nanoparticles as electrodes to prepare solution-processed OLEDs, PEDOT:PSS/silver nanowires can also be used as the anode of solution inversion devices.⁷⁰ Although these all-solution OLED devices have the potential to reduce production costs, the efficiency of the devices reported so far is relatively low, and there is no further research on stability; so there is still a long way to go to meet the market requirements.

3.2 Inverted hybrid device structure

Organic/inorganic hybrid structure refers to the mixture of an inorganic injection/transport layer and an organic EML. It is usually inverted, and the n-type metal oxide is deposited on ITO as an EIL/ETL, and electrons are transferred from the conduction band of the n-type metal oxide to the LUMO level of the EML. Finally, a high work function and stable metals (e.g., gold and platinum) are used as anodes.¹⁶⁷ Commonly, a layer of metal oxide with a deep conduction band energy level is also deposited between the EML and the anode to increase the hole injection capability. The advantage of the hybrid structure is the use of stable injection/transport layers and the avoidance of reactive cathodes (e.g. Li/Al, Ba/Ag, Ca/Al), thus enhancing the lifetime of the device. At the same time, the structure is also simple, and a suitable injection layer is matched to improve the injection of carriers, which can better improve the efficiency of the device.

In the inverted hybrid structure, expensive vacuum-evaporated transition metal oxides are usually used as the HIL/HTL, which is not cost-effective. The reason for not using the low-cost solution method to prepare transition metal oxide films is due to the various problems of solution method transition metal oxides: the film roughness is large, the film contains defects, the work function decreases, the precursor diffuses to the active layer, which degrades its performance, and the film takes a long time to form. Therefore, only a few literature studies demonstrate the all-solution-processed method for preparing the transport layer. For example, in 2012, the use of a hydrolyzed solution method instead of vacuum evaporation to prepare the HIL/HTL (V_2O_5) and the ETL (ZnO), respectively.¹⁶⁸ However, this work did not tap the potential advantages of the hybrid structure in terms of the optoelectronic performance and lifetime of the device. The inverted hybrid structure is limited by transport materials, especially HIL/HTL materials, and cannot obtain high-quality thin films, which greatly limits its performance. In addition, due to the energy level matching, the inverted hybrid structure cannot make full use of most of the materials suitable for the upright structure, which leads to the inflexible membrane structure design. By breaking through the bottleneck of transmission materials and expanding the flexibility of the membrane structure design of inverted hybrid OLEDs, the organic/inorganic hybrid structure is expected to gain greater development space.

3.3 Tandem device structures

The tandem structure is a device structure in which multiple light-emitting units are connected in series through a connection layer. At very low currents, devices based on the tandem structure can achieve high brightness. Under the same current density, since the aging characteristics of the tandem OLED

and the traditional single OLED are the same, and the initial brightness of the former is larger, the lifetime of the tandem OLED is longer than that of the traditional OLED under the same initial brightness. In addition, tandem OLEDs are also characterized by operating the voltage and current efficiency proportional to the number of tandem cells, but the PE does not increase.

Generally, more than 10 functional layers can be prepared by vacuum evaporation between the anode and the cathode of a series device with two luminescent units. However, due to the limitation of solvent orthogonality, the preparation of these functional layers by solution methods is a great challenge. In 2014, inverted OLEDs were reported to be prepared by a solution method; WO_3 /PEDOT:PSS/ZnO/PEI was used as the charge generation layer to connect two polymer light-emitting units in series as shown in Fig. 10a, and enhanced optoelectronics performance was obtained.¹⁶⁹ Next, Kido's team demonstrated a positive series OLED, where phosphomolybdate hydrate (PMA)/TFB is used as a charge generating layer and two polymer luminescent units are connected in series, as shown in Fig. 10b.¹⁷⁰ After this, they replaced the polymer material with a higher-efficient small-molecule material, and used PEDOT:PSS/neutral PEDOT:PSS as the conductive connection layer to prepare a solution-processed phosphorescent tandem OLED as shown in Fig. 10c.⁶⁹ Finally, the green tandem OLED achieved a CE of 94 cd A^{-1} and a PE of 18.6 lm W^{-1} , and the tandem WOLED achieved a CE of 69 cd A^{-1} and a PE of 14.1 lm W^{-1} .

It can be seen from the above examples that the CE of the series structure is relatively high and the PE needs to be further improved. At the same time, it can also be concluded that the tandem structure of the solution method is more complicated, which increases the cost of device production.

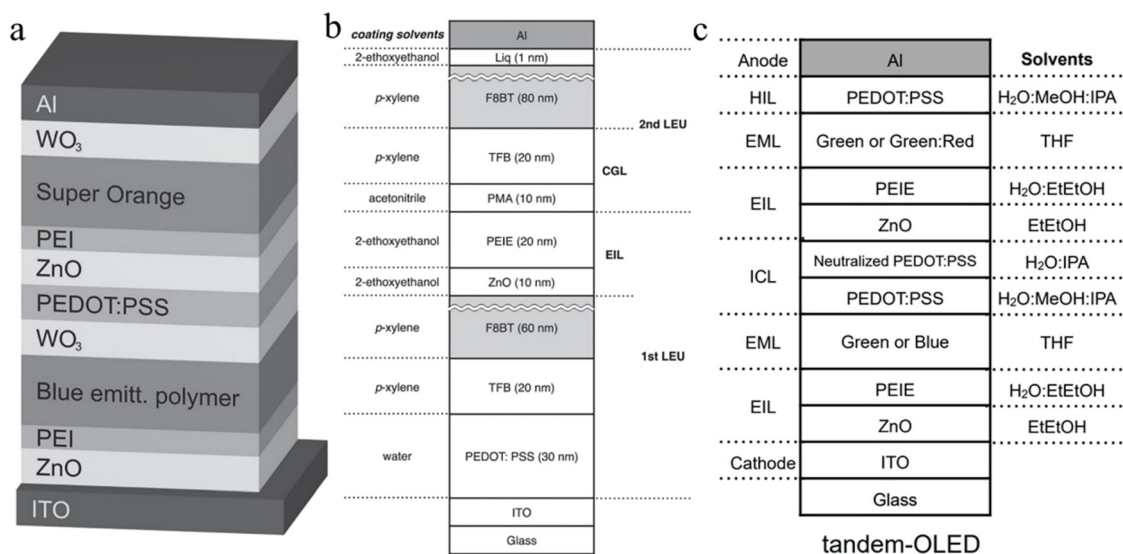


Fig. 10 Solution-processed OLEDs. (a) Inverted tandem OLED.¹⁶⁹ Copyright 2014 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (b) Positive tandem OLED¹⁷⁰ (Copyright 2014 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim) and (c) phosphorescent tandem OLED.⁶⁹ Copyright 2015 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim.

3.4 Critical problems

Despite the above discussion about the structure of solution-processed OLEDs, solution-processed OLEDs also face morphological challenges. For solution-processed OLED systems composed of multiple components, such as polymer–small molecule mixed systems and polymer–polymer mixed systems, phase separation is difficult to avoid in the operation of devices,^{171,172} which will seriously affect various performance parameters of devices (such as efficiency, brightness, and lifetime). In order to solve these problems as much as possible, the use of solvents or mixtures of solvents with a special polarity solvent strategy is conducive to the construction of uniformly dispersed multi-component films.^{173,174}

Compared with the devices of the evaporation method, the quality control of the film forming process of the solution method is difficult to maintain. The molecular orientation is chaotic, the interface fluctuation is large, and the thickness of the same film is not uniform, which has a certain impact on the interface contact and carrier transmission of the liquid method film.^{175–183} To date, there are no general guidelines that are good at assessing and avoiding morphology-related problems in solution-processed OLEDs. In order to develop high performance solution-processed OLEDs, these problems should be carefully studied and appropriately solved.

Molecular orientation. For vacuum evaporation OLEDs, the strategy to improve the molecular horizontal emitting dipole orientation has made a lot of achievements, but for solution-processed OLEDs, it is still a big problem. Duan *et al.* proposed a strategic molecular design of a solution-processable TADF emitter with a high dipole orientation by attaching a flexible chain terminating in the bipolar 9,9'-spirobi[fluorene] subunit to the TADF emission core as an anchoring-group.¹⁸⁴ It was found that the anchoring group not only enhances the horizontal orientation by increasing the molecular flatness, but also facilitates the luminescence of the original film. The corresponding undoped solution-processed OLED confirmed unprecedented maximum EQEs (up to 30%). At the same time, combining these compounds as TADF sensitizers and multi-resonance ultimate emitters, solution-processed OLEDs achieve 25.6% EQE_{max} with a half-width narrow to 29 nm.

Film forming capability. The ability to form a film also affects the quality of the film in the solution preparation process to a certain extent. Due to the short molecular chain, when a solvent is added, small molecules form a very dilute solution. This problem limits the solution to forming thicker films, which also affects the compactness of the films; in addition, small molecules are prone to crystallization due to their low glass transition temperature (T_g). Therefore, to ensure a high T_g , the molecule must have a non-planar molecular chain or a structural rigid group, such as naphthalene, biphenyl, carbazole, fluorene, *etc.*^{185,186} The increase in the length of the molecular chain also increases T_g , improving the stability of the membrane.

Film integrity. In order to obtain a highly complete film, the purity of the solution is crucial. If the solution is impure and contains minute particle contamination, the formation and

growth of isolated crystal nucleation centers is highly likely. This would make the deposition of small molecules more challenging. In addition, the direct entanglement of molecular chains is indispensable in the solution. Without such a molecular interaction, there may be voids or holes left in the film after solvent evaporation. Therefore, it is very important to adopt the strategy of molecular modification to control the relationship between molecules.¹⁸⁵

4. Printing display technology

Solution-based printed OLED technology has recently attracted much attention from the display–screen industry. The display companies such as Samsung Display and LG Display hold several patents of the key technologies in solution-processed OLEDs. Compared with solution-processed OLEDs, currently, the most mature and reliable vacuum-deposited OLED technology with the highest technical index also has its demerits, such as high preparation cost, low material utilization rate and an inaccurate doping ratio of organic materials.^{9,148,184,187–189} Because of the huge potential of solution-processed OLED technology in large area and flexible device fabrication, it has the possibility to make the production and preparation of OLEDs as convenient as printing books in the future. Considering this superiority, it is critical to find a new method to replace vacuum-deposited technology. Printed OLED technology is a method to prepare thin films for OLEDs by using solution which is dissolved in organic solvents or other solvents. It always contains spin-coating, ink-jet printing and screen printing methods.^{190–192} In addition, the concentration and doping ratio of materials for solution-processed methods can be precisely adjusted, even with a low doping concentration. Here, we will introduce some representative solution-based methods and their applications for OLEDs in detail.

4.1 Spin-coating

Spin-coating and evaporation are both main techniques for thin film deposition which are frequently used in laboratory and industrial electronic device fabrication. Fig. 11a shows a schematic diagram of the spin-coating process.

The so-called spin-coating method is using a vacuum pump to firmly absorb the substrate layer on the vacuum port, and then the prepared solution is dropped on the substrate. By utilizing centrifugation, the wet film will be formed by a given rotation speed, acceleration and time. Next, the wet film is transferred to a heating plate for annealing, with the aim of drying the solvent in the solution and further obtaining a dense smooth film. In the preparation process of spin-coating, the morphology of the film is also related to other conditions, such as solvent atmosphere in the glove box, the concentration of solution, humidity and oxygen conditions. And these factors can be adjusted to optimize device performance.¹⁹³ In 1990, Burroughes *et al.* from Cambridge University synthesized poly(*p*-phenylene vinylene), a polymer with excellent air stability, and realized the preparation of OLEDs by the spin-coating

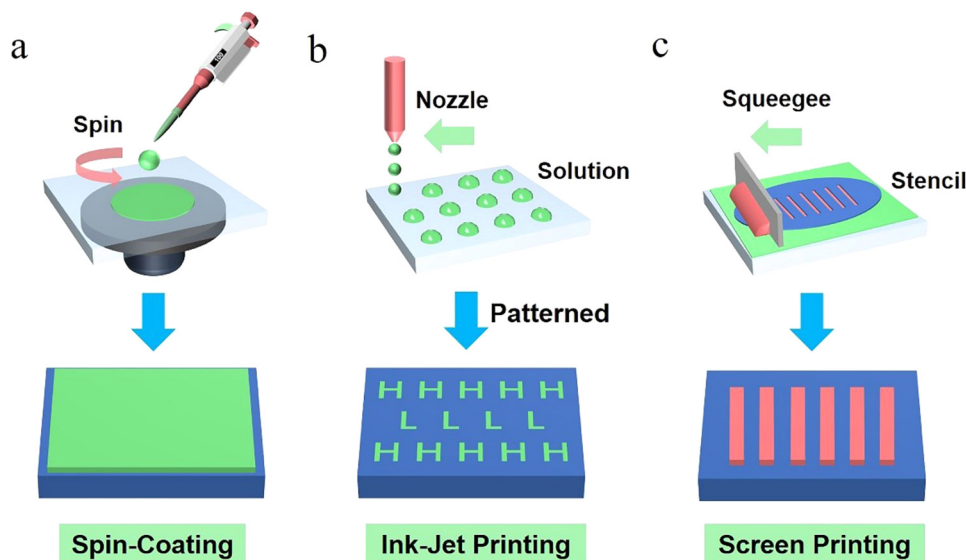


Fig. 11 The common methods for solution-processed OLEDs: (a) spin-coating, (b) ink-jet printing and (c) screen printing.

method for the first time,⁹ thus setting off a great wave of solution-processed OLEDs.

In recent years, OLED fabrication by the spin-coating method also has made great breakthroughs. In terms of the luminescent layer, Sree *et al.* designed three phosphorescent iridium(III) complexes in 2018. The Ir 1 complex prepared by the spin-coating method achieved an EQE of 24.22%, and the corresponding CE reached 92.44 cd A⁻¹. Moreover, when the brightness is 10 000 cd A⁻¹, it can still maintain 22.91% EQE, showing a low efficiency roll-off.¹⁹⁴ In addition, TADF, as the third generation emitter of OLEDs, has also made groundbreaking achievements in the spin-coating method. As mentioned above, TADF materials prepared by the solution method can be divided into three types, containing a polymer, a small molecule and a dendritic molecule. In the context of fewer reports on polymer TADF materials, Ren *et al.* introduced styrene as a copolymer into the 2-(10*H*-phenothiazin-10-yl)dibenzothiophene-*S,S*-dioxide TADF material in 2016. By controlling the ratio of the TADF unit and styrene unit, an optimal EQE of 20.1% can be obtained for OLEDs by the spin-coating method at a unit ratio of 37%:63%(Copo1).¹⁹⁵ In 2018, Colella *et al.* reported OLEDs based on the spin-coating method of small molecules 9-[2,8]-9-carbazole-[dibenzothiophene-*S,S*-dioxide]-carbazole (DCz-DBTO2) and 4,4'-cyclohexylidenebis[*N,N*-bis(4-methylphenyl)benzenamine] (TAPC).¹⁹⁶ By changing the ratio of chlorobenzene and chloroform solvent, the film thickness and morphology of the small molecule excimer complex were controlled, and an optimal EQE of 8.9% was finally obtained. Besides, in 2019, Liu *et al.* synthesized four dendritic molecules 5CZBN-O-Cz, 5CZBN-O-2CZ, 5CZBN-CZ and 5CZBN-2CZ. Based on the spin-coating method, solution-processed OLEDs with a low turn-on voltage and high device efficiency were obtained, and the OLEDs based on the 5CZBN-2CZ TADF dendrimer even created more than 20% EQE which was comparable to vacuum evaporation devices.¹⁹⁷

Lee *et al.* utilized the high triplet state energy level and good solution processability of tetraphenylsilane (with pyridine moieties) to prepare the electron transport layer by the spin-coating method, and obtained EQEs of 29% and 35.5% for green light and orange-red light solution-processed OLEDs, respectively.¹⁹⁸

However, in terms of the thermal vacuum deposition process, the advantages of the spin-coating process are reflected in its convenient operation, precise control of doping ratio and large-area fabrication. Due to the operation properties of spin-coating, the waste of a large amount of solution is inevitable, and the utilization rate of the material tends to be low. Moreover, the single operation step also greatly limits the realization of patterned fabrication and full-color display, and makes it more suitable for the preparation of monochrome light-emitting diodes. Therefore, the following issues need to be solved urgently. Firstly, many small molecule materials hold a relatively low solubility in some common solvents, which hampers the formation of a complete film. Secondly, when multilayer devices are prepared by the spin-coating method, the solution in the upper layer may dissolve the solution in the former layer, resulting in an uneven morphology of the overall film, inhibiting the effect of each functional layer, and thus resulting in low device efficiency.¹⁹⁹

Researchers have also put forward many measures to improve the above problems. In 2015, Cho *et al.* reported a method to change the molecular solubility and luminescence color by introducing F as electron withdrawing. Both the two blue synthesized TADF emitters can break the 20% EQE, which is comparable to the performance of the device prepared by the evaporation technique.²⁰⁰ In the preparation of full-solution OLEDs, Liu *et al.* replaced CB and CF, commonly used solvents of poly(9-vinylcarbazole) (PVK), with 1,4-dioxane orthogonal solvent in order to overcome the problem of the redispersion of solution. The use of orthogonal solvents not only did not destroy the luminescent layer, but also retained the integrity of

each functional layer. Finally, the prepared blue QLED devices based on the PVK/TFB hole transport bilayer may achieve a 25-fold increase in luminous efficiency.²⁰¹

4.2 Ink-jet printing

The spin-coating method has the advantages of simple operation and large-area preparation, while it is not satisfied with the high industrial demand with respect to the continuous improvement of the OLED manufacturing technique. As a result, printed electronics, which combine solution and advanced printing equipment, are becoming mainstream. Among them, ink-jet printing technology, as one of the most common printing technologies, can realize the preparation of patterned preparation, high-resolution display and full-color display. What's more, it can even overcome the material waste caused by the spin-coating method and achieve a high material utilization rate of more than 90%. Based on the above advantages, ink-jet printing is also considered to be the most suitable technology for preparing large-area OLED display panels.¹³¹

Since the invention of the 19th century, inkjet printing has been widely used in biological chips and organic thin-film transistors.^{202,203} As a kind of printing technology, the biggest advantage of the inkjet printing is that it does not need to customize the expensive and complex templates in advance, and can write electronic patterns through computer control heads (Fig. 11b). In the ink-jet process, micrometer-diameter nozzles deposit small ink droplets onto the designed pattern at a rate of several thousand drops per second. The ink will go through four stages, namely, the ejection of ink droplets, the flight of ink droplets, the contact between ink droplets and the substrate, and the drying of films, which are affected by many factors.^{204,205} Generally, ink-jet printing equipment will have a number of nozzles, which are responsible for different colors of luminescent material inks and written into the corresponding groove, forming pixels.

First, the choice of solvent is critical in determining the stability of the process and printing behavior. In the ink-jet process, the ink should not block the nozzle, and it must have appropriate viscosity and surface tension to fully soak the designed pattern and improve the repeatability of the ink-jet process. Take polymer materials as an example, when choosing the solvent for the polymer ink, the frequently used volatile solvents in the spin-coating method, such as toluene and xylene, should be replaced by solvents with higher boiling points, such as trimethylbenzene and tetramethylbenzene. It is worth noting that polymer inks with high viscosity can greatly reduce device efficiency and hinder ink ejecting. In addition, when the surface tension of the ink droplet is too large, it will cause the phenomenon of droplet tail, which highly affects the quality of the pattern. Meanwhile, excessive soaking of the substrate will occur when the surface tension is too small. With reference to the aforementioned situation, it is very important to find a suitable ink.²⁰⁶

The key technology of ink-jet printing lies in the way of how to generate the droplets, which can be divided into continuous ink-jet (CIJ), drop-on-demand ink-jet (DOD) and electrospray

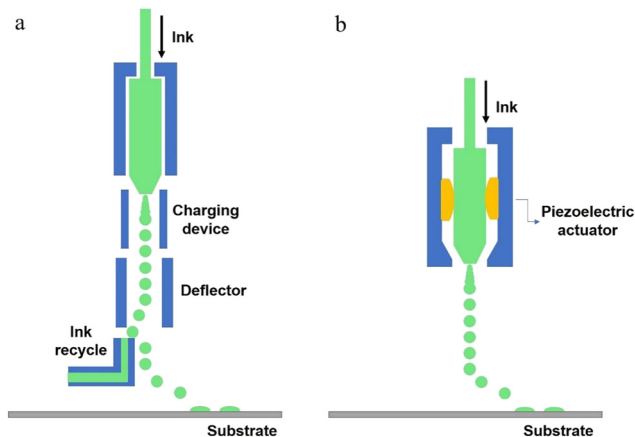


Fig. 12 Schematic diagrams of (a) continuous ink-jet and (b) piezoelectric drop-on-demand ink-jet.

technology.²⁰⁷ The schematic diagram of CIJ is shown in Fig. 12a. The ink is pressed out of the nozzle through the liquid column, presenting continuous and fractured ink droplets due to the “Rayleigh-plateau” instability. To precisely locate the ink at a point, the CIJ technique requires a charging device to form a charge on the droplets, followed by a recovery device to retrieve the remaining ink into a storage device. The diameter of CIJ droplets is generally about 100 μm , slightly larger than the diameter of the nozzle, the frequency of droplets is in the range of 20–60 kHz, and the droplet flight speed is up to 10–30 m s^{-1} .

Because of the large diameter of droplets for CIJ technology, the problem of fine control needs to be overcome, and it is not conducive to the preparation of electronic devices. Moreover, CIJ technology includes a charging device, a deflector and a droplet recovery device, which is too complicated and expensive. The appearance of DOD ink-jet makes up for the deficiency of CIJ technology. First, DOD ink-jet works only when it is needed, resulting in significant cost savings. It can produce droplet sizes in the range of 20–50 μm , which makes it the most popular ink-jet technology in the field of micron electronic devices. According to different nozzles, DOD ink-jet can be divided into piezoelectric (Fig. 12b) and thermal foaming. Piezoelectric ink-jet printing is a technology that relies on changes in piezoelectric crystals to extrude the ink, while thermal foaming is a technology that relies on the rapid heating of the ink to vaporize it. Comparing these two methods, piezoelectric ink-jet has great superiority in cost, but the technical stability is not as good as the thermal foam ink-jet.

In addition, electrospray technology must be carried out under the condition of applied electric field and has high demand for the ink. The droplet size for electrospray technology is small and susceptible to electrowetting. This technology has the highest resolution compared to CIJ and DOD ink-jet, but it is rarely reported because the ink needs to be charged (Table 1).

Ink-jet printing has many advantages in the preparation of electronic devices. Generally speaking, it can be used to deposit

Table 1 Comparison of ink-jet printing technologies

Types	Cost	Drop speed	Accuracy	Drop diameter	Frequency
Electrospray technology	High	—	High	Small	—
Continuous ink-jet	High	10–30 m s ⁻¹	Low	100 μm	20–60 KHz
Drop-on-demand ink-jet	Low	5–8 m s ⁻¹	High	20–50 μm	1–20 KHz

one or multiple functional layers, and the performance of the device is not easily affected by the substrate.²⁰⁸ Secondly, the process is simple and convenient for mass preparation, and the utilization rate of the material is up to 98%. The film quality is relatively high. Thirdly, compared with other printing technologies, ink-jet printing is more accurate and has more advantages in realizing patterned preparation and full-color display.^{209–212}

In 1998, Hebner *et al.* combined the spin-coating method and ink-jet printing for the first time. For the HTL material PVK, emitting materials coumarin 6 and coumarin 47 were dissolved in chloroform to make the inks with the ratios of 10 g L⁻¹, 0.1 g L⁻¹ and 0.01 g L⁻¹, respectively. Then the ink was printed on the polyester fiber treated ITO with the help of the office printer.¹⁰ Bharathan *et al.* also used a commercial printer to print the PEDOT ink in specific areas in this year. In this work, they combined the spin-coating method to spread the MEH-PPV buffer layer on PEDOT, and successfully realized the graphic display.²¹³ Besides, in 1999, they also realized dual-color and full-color PLED displays by combining spin-coating and ink-jet technology for the first time. Since then, more and more work of ink-jet printing OLEDs has been reported. In 2013, the world's first full-color OLED display based on printing technology was reported by Zheng *et al.*¹⁶⁶ In 2018 and 2020, BOE successfully produced OLED displays with resolutions of 4K and 8K by using ink-jet printing technology.²¹⁴

However, there are still many technical difficulties in ink-jet printing technology, among which the biggest difficulty is the coffee ring problem. The so-called coffee ring effect is a phenomenon of uneven thickness distribution of a solute at the center and edge of the substrate.²¹⁵ When the ink droplets contact the substrate, the solvent volatilizes faster at the edge than at the center. Due to the capillarity, the fluid in the middle will flow to the edge, resulting in an uneven distribution of the film. Therefore, we need to further optimize the ink or combine the post-treatment method to suppress the coffee ring effect and further improve the film quality of the device. In 2020, Du *et al.* used cyclohexanone as the main solvent, combined with cyclohexylbenzene and benzyl alcohol cosolvents with high viscosity and high boiling point, and successfully inhibited the capillary flow of ink droplets from the center to the edge.²¹⁶ Moreover, we can also introduce surfactants into the ink to fully wet the surface of the substrate, thus inhibiting the coffee ring effect.^{215,217}

In addition to the above problems, ink-jet printing still has the following several main problems. Firstly, the present stage of ink-jet equipment and factory construction is not perfect and it still needs to be further optimized. Secondly, the resolution of

ink-jet printing has been improved to nearly 300 PPI. However, compared with pure evaporation, the process still needs to be improved, which also requires us to do further research on the pixel structure. Also, ink-jet printing has interface wetting. From the interface point of view, the wetting problem in inkjet printing is mainly the interface wetting problem of the ink printing substrate. For solid substrates, various surface modifications and treatments can be applied so as to improve the wetting effect between the liquid phase and the solid phase, or to produce wettability differences in different areas of the substrate and to limit the wetting behavior of the liquid phase on specific solid phase areas to achieve special printing requirements.

4.3 Screen printing

Screen printing has a history of more than two thousand years. It is famous for its low cost and environmental protection. As a universal printing technology, it has the characteristics of patternable, large-area and flexible preparation, and is also frequently used in the field of photoelectric devices such as field-effect transistors and solar cells.^{218–222} The screen printing squeegee ink through the hollow part of a screen stencil (as shown in Fig. 11c), resulting in a specific pattern deposited on the substrate. Depending on the printing method, screen printing can be classified into flat–flat, flat–rotary and rotary–rotary methods. Specifically, the plane of the substrate and the screen plate of the flat–flat method is fixed and parallel to each other in the printing process, only through the movement of the squeegee to achieve patterned printing. The flat–rotary is to fix the squeegee, move the screen stencil and rotate the roller to achieve material printing. For the rotary–rotary method, the screen stencil is fixed on the roller, through the rotation of the upper and lower rollers to imprint the ink on the substrate.

From the above three printing methods, we can conclude that screen printing is mainly composed of the screen stencil, printing table, squeegee, substrate and ink. For the selection of screen stencil materials, high precision and water-soluble inks generally choose the stainless steel screen stencil whose current accuracy can reach the micron level. What's more, according to the properties of ink and accuracy requirements, polyester or nylon materials can also be selected to make the screen stencils. However, compared with ink-jet printing, screen printing requires a very high viscosity of ink, even up to 100 000 cP, but the increase in viscosity will correspondingly increase the difficulty of printing and even have a great impact on the continuity and edge uniformity of the printed pattern. In addition, screen printing can produce the thickest film of all printing processes but with low production efficiency.²⁰⁹ Similar to the spin-coating method, the film thickness can be

adjusted by changing the ink concentration. In the case of low viscosity ink, low squeegee speed, low ink concentration and high screen number will make the thickness of the printed film thinner, and even lead to the imperfection in the deposited layer. Therefore, continuous patterns and uniform film thickness can only be obtained with an appropriate control of the above factors.

Screen printing has shown its potential in printed electronics since World War II and has been used to produce thin film resistors. In 1980, Nakayama *et al.* successfully prepared CdS/CdTe solar cells by using screen printing technology,²²³ and since then, there have been more and more reports about screen printing electronics. In 1997, Bao *et al.* deposited ITO on a flexible substrate of polyethylene terephthalate (PET). Combining with the screen printing technique, they deposited the polyimide dielectric layer on ITO and then printed poly(3-hexylthiophene) (P3HT) which is dissolved in chloroform onto the dielectric layer. Finally, the electrode ink was also printed by screen printing and the first full-printing field effect transistor was made.²²⁴

Among all kinds of printing technologies, screen printing is the earliest printing technology used in OLED production. In 2000, Jabbour *et al.* successfully applied screen printing to polymer light-emitting diodes prior to the successful preparation of screen-printed solar cells. They used screen printing to print the mixed ink of polycarbonate and TPD (mass ratio = 1:1) onto ITO substrates as a hole transport layer.²²⁵ In the following year, Birnstock *et al.* used screen printing technology to deposit PEDOT transport layer and polymer luminescent layer on ITO glass, and combined with vacuum evaporation technology to prepare the Ca-Ag electrode. Finally, they

successfully prepared the 43×26 mm PLED display, which even exceeded the performance of the spin-coating OLED at that time.²²⁶ Lee *et al.* also succeeded in preparing high-performance phosphorescence PLEDs in 2008 and 2009, respectively.^{227,228} In 2017, Preinfalk *et al.* combined the strategy of introducing an internal extraction layer to print a kind of polymer ink that mixed with high refractive index TiO_2 particles onto the substrate by using screen printing (Fig. 13a–d). The EQE of their prepared OLED has been improved by nearly 56%.²²⁹ The PEDOT:PSS electrode prepared by the spin-coating process can greatly improve the performance of OLEDs. Based on this strategy, in 2018, Zhou *et al.* prepared the reticular PEDOT:PSS transparent conductive film by screen printing on the flexible PET substrate, and combined with doping and pretreatment strategies to reduce the square resistance of the electrode to further improve the performance of the device (Fig. 13e and f). Finally, the luminous efficiency and current efficiency of the screen printed device reached 1.83 lm W^{-1} and 3.40 cd A^{-1} , respectively, and could still work under bending conditions.²³⁰

Compared with other similar printing methods, screen printing is not easily limited by equipment. It has the possibility of ultra-large area preparation and can be widely used in the preparation of flexible devices. However, as a mature printing technology, there are still many problems. First of all, screen printing requires a high viscosity of ink, which greatly limits the choice of materials. Therefore, it is often used in polymer printing, and there are few reports about small organic molecules with low viscosity. Secondly, although the mesh diameter can reach the micron level, the printing effect is not as good as ink-jet printing. Finally, the screen array currently used is still

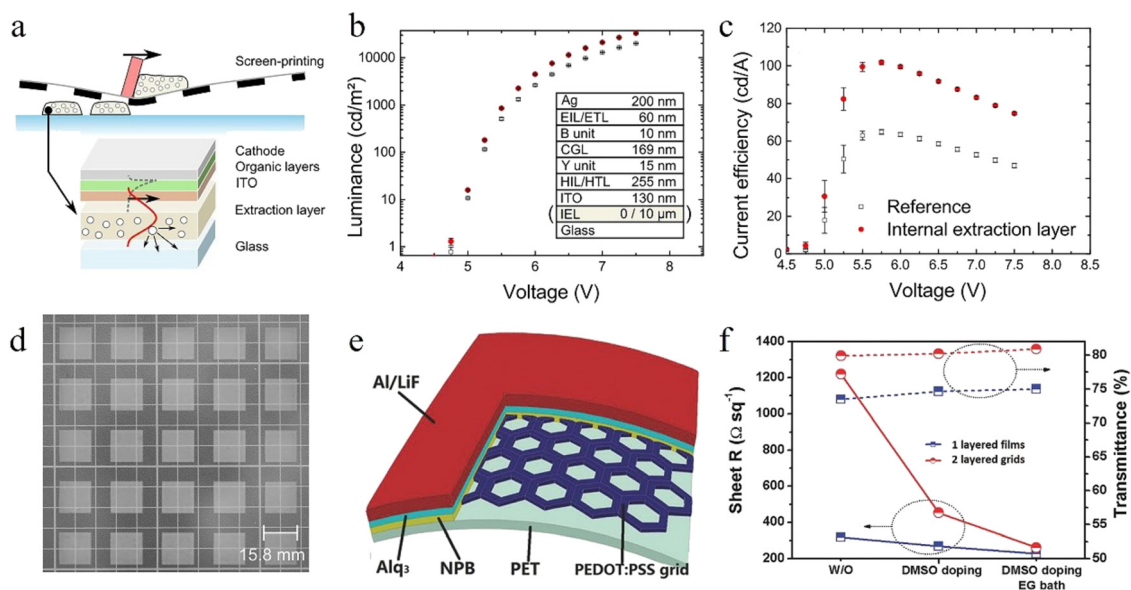


Fig. 13 (a) Schematic diagram of the screen-printed internal extraction layer. Improved optoelectronic properties of the WOLEDs following the introduction of the IEL. (b) Luminance and (c) current efficiency of the devices with (red dots) and without (white squares) the IEL. (d) Photographic image of the complete screen-printed IEL layout.²²⁹ Copyright 2017, American Chemical Society. (e) Layer structures of experimental OLEDs with screen-printed PEDOT:PSS grid anodes. (f) Sheet resistance and light transmittance of screen-printed PEDOT:PSS anodes treated by DMSO doping and EG bath.²³⁰ Copyright 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim.

relatively simple, while the more complex and larger size of the screen array remains to be further studied. If the above problems can be effectively overcome, then screen printing in the field of printed electronics will have a broader application prospect.

4.4 Roll-to-roll coating

The roll-to-roll technique plays a very important role in printed electronics. It is a fabrication process of nano-scale electronic products on flexible substrates or metal films. In recent years, the preparation of large-scale flexible electronic devices has attracted much attention, and the roll-to-roll coating process is also considered as the best process for the deposition of organic electronic solution on large-scale flexible substrates.^{231–233}

Roll-to-roll coating can be divided into gravure printing, blading coating and slot-die coating. In fact, the screen printing described in the last chapter can also be regarded as a roll-to-roll coating process. However, its compatibility with roll-to-roll technology is still not ideal due to its high ink viscosity requirements and relatively slow processing speed.

4.4.1 Gravure printing. As an efficient and high-yield printing technology, gravure printing displays a high printing speed of $60 \text{ m}^2 \text{ s}^{-1}$, while the most sophisticated ink-jet printing is only $0.01 \text{ m}^2 \text{ s}^{-1}$. Fig. 14a shows the schematic diagram of gravure printing.¹⁹¹ The ink is first applied to intaglio, and then a scraper is used to scrape off the excess solution on the surface. The remaining ink is transferred from intaglio to the substrate by pressure. Finally, the patterned film is formed

after drying. This technology is widely used in transistors. In particular, the combination of gravure printing and flexography can also be used to produce large-scale organic solar cells. Nevertheless, the same as screen printing, its viscosity requirement is strict, which will make it hard to control the thickness and quality of the prepared film and further inhibit the development of this technology in the field of printed electronics.²³⁴ In 2005, Nakajima *et al.* first reported the flexible OLED panel based on gravure printing. Although the technical formula and device efficiency were not published at that time, the OLED panel based on this technology can operate for nearly 1000 hours with an initial brightness of 100 cd m^{-2} .²³⁵ In 2010, Chung *et al.* succeeded in printing PEDOT:PSS HTL and the LUMINATION™ Green 1300 (LG 1300) polymer luminescent material onto the ITO substrate by using gravure printing (Fig. 14). The fabricated PLED achieved a maximum brightness of $66\,000 \text{ cd m}^{-2}$, which is comparable to the green OLED prepared by traditional technology at that time.¹⁹²

4.4.2 Blading coating and slot-die coating. In order to overcome the problems caused by high viscosity ink, there is an urgent need for a printing method that can have good compatibility with any viscosity of ink, and blading coating and slot-die coating can just make up for the deficiency of gravure printing.²³⁶ Both of these roll-to-roll techniques deposit the material by fixing the nozzle and moving the roller. The difference is that the distance between the scraper and the substrate is very small for blading coating. The ink is accumulated in front of the fixed scraper, and then the film is prepared just by the relative movement between the scraper and the roller. For slot-die coating, there is a certain distance between the scraper and the substrate and there is no need to squeeze out the ink in advance. A certain dose of ink in the scraper and substrate will form a vertical bending surface, whose shape can be used to control the width of the coating.

In terms of thickness control, the above methods can both adjust the film thickness by changing the running speed and the distance between the scraper and the substrate, but blading coating is more suitable for printing with a wide area and no fine patterns. As mentioned earlier, this kind of printing technology is highly compatible with the inks of different viscosities or different solvents, and accordingly, the requirements for the wettability of the substrate are not high. But for the water-based ink with excessive surface tension, plasma pretreatment can also be used to improve the wettability. Different from slot-die coating, double-slot-die coating can simultaneously realize the deposition of multilayer film. It can also achieve high efficiency and high yield printing with a running speed of 1 m min^{-1} . Even though its performance is unremarkable in practical applications, it can provide a new idea for the future printed electronics.

Roll-to-roll has limitless foreground as a new kind of printing technology. First of all, from the long-term point of view, environmental protection has always been considered as the most significant point in production. Therefore, the future trend of printed electronics production needs to focus on diversification, aiming to develop different types of inks such

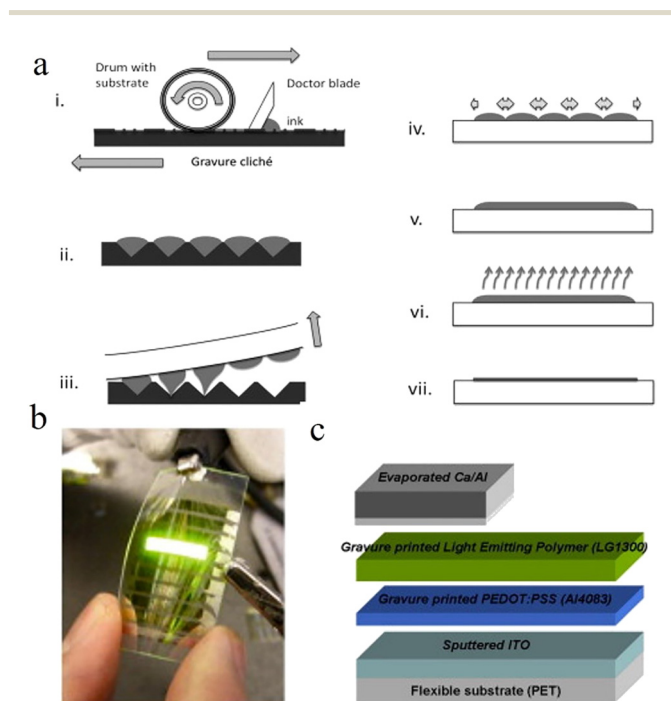


Fig. 14 (a) Gravure printing process. (b) Photograph of light emission from a fully printed flexible PLED of fully gravure printed and fully spin-coated PLEDs. The size of the light emission area is 0.42 cm^2 (width: 1.4 cm , height: 0.3 cm). (c) Structure of gravure printed PLEDs.¹⁹² Copyright 2010 Elsevier B.V.

as emulsions, solutions and nanoion dispersion solution. Besides, we can also replace the toxic solvents such as chloroform with more environmental solvents. Secondly, for roll-to-roll multilayer printing, its requirements for equipment and operation procedures are very high, which needs to be further optimized by experts in the future.

4.5 Other methods

In addition to the above printing technologies, there are also some atypical solution methods, such as the flash evaporation and dip coating.^{237,238} In 2017, Wang *et al.* reported a flash evaporation method. They first coated organic solution on a silicon substrate and then the organic solvent rapidly volatilized from the silicon wafer by changing the current of the vacuum evaporation heater.²³⁷ The organic film prepared by this method is too fast to affect the morphology of the former layer, but the development of industrial preparation will be limited by equipment. Compared with flash evaporation, the dip coating method is easier to operate and not limited by equipment. We just completely immerse the substrate in the solution for a period of time and then take it out and dry it into a film. This method is also frequently used in the experimental preparation process, which can control the thickness of the film by adjusting the soak time. Moreover, it has the advantage of high material utilization and is friendly to large-area film preparation. In 2018, Xie *et al.* successfully prepared the hole transport layer and small molecule luminescent layer based on the dip coating method and applied them to OLEDs. The performance of devices based on this method is even higher than that of other conventional processes.²³⁸

5. Summary and perspectives

Herein, we systematically reviewed the development history, unique advantages, progress and challenges of solution-processed OLEDs for printing displays. First, we introduced the electrodes, injection layers, transport layers and emitting layers from the perspective of materials. As we all know, the widely used commercial transparent conductive films are mostly indium tin oxide (ITO). Although it can show excellent performance of more than 90% light transmittance, its high price, brittleness, poor bending resistance and other problems cannot be ignored. Therefore, it is of great significance to find a kind of transparent conductive film material which is cheap, easy to prepare, widely used and easy to integrate into flexible devices. We have studied and summarized several common conductive electrodes (metal electrodes, carbon nanomaterials, conductive polymers and composite electrodes). Then, we introduced the hole injection layers, electron injection layers, hole transport layers and electron transport layers in detail. Then, we introduced OLED printing materials from the perspective of small molecules and polymers.

Second, the development, progress and difficulties of solution-processed OLEDs are introduced from the perspective of monochromaticity, lamination, inversion and other structures.

Compared with evaporated OLEDs, multilayer structures for solution-processed OLEDs are difficult to prepare because of the possible problems of interlayer diffusion and compatibility. In view of the above problems, this review focuses on several typical solution-processed OLED device structures and their preparation methods.

Third, we introduced various possible preparation methods of printed OLEDs, and carried out some comparative studies of the film-forming characteristics, as well as the device performance, explaining their advantages and disadvantages and development trend. Printed OLED technology includes spin-coating, inkjet-printing and screen-printing methods. In addition, the doping concentration of printed OLEDs can be accurately adjusted even though its value is very low. Here, we summarized some representative printed OLED methods and their applications in detail.

Printed OLEDs still have the following challenges: the lack of systematic basic research on the synthesis process, property regulation and engineering scaling of new materials on the electronic, atomic and molecular scales, which makes it difficult to provide theoretical guidance for the engineering scaling of material preparation; the need to consider the compatibility of the design and development with the matching ink formulation, the inkjet printing process, thin film packaging technology, *etc.* Printing material preparation, purification and separation are not green processes, and still face the problems of long separation and purification processes and high emission. Nevertheless, the rapid development of printed OLEDs in recent years has endowed them with great potential for their application in the future lighting and display technology. We believe that printed OLEDs prepared by inkjet printing will be the mainstream direction of the development of display technology in the future. With the improvement of printing OLED technology, the future display screens will be lighter, cheaper and clearer.

Conflicts of interest

The authors declare no conflicts of interest.

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